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Wallikewitz et al.

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(54) **ORGANIC LIGHT-EMITTING DIODE INCLUDING AN ELECTRON TRANSPORT LAYER STACK COMPRISING DIFFERENT LITHIUM COMPOUNDS AND ELEMENTAL METAL**

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See application file for complete search history.

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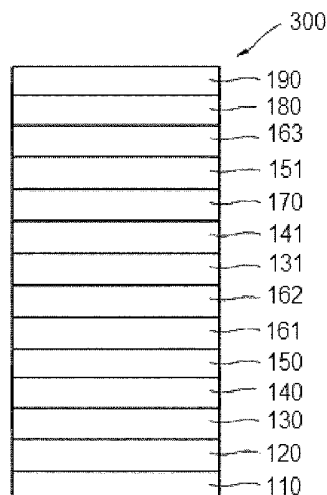
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(57) **ABSTRACT**

The present invention relates to a an organic light-emitting diode (OLED, **100**) comprising at least one emission layer (**150**), and an electron transport layer stack (**160**) of at least two electron transport layers, wherein a first electron transport layer (**161**, **162**) and a second electron transport layer (**162**, **161**) comprises at least one matrix compound and in addition, —the at least first electron transport layer comprises a lithium halide or a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or—the at least first electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the at least second electron transport layer comprises a lithium halide or a lithium organic complex; wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the

(Continued)



electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex.

30 Claims, 3 Drawing Sheets

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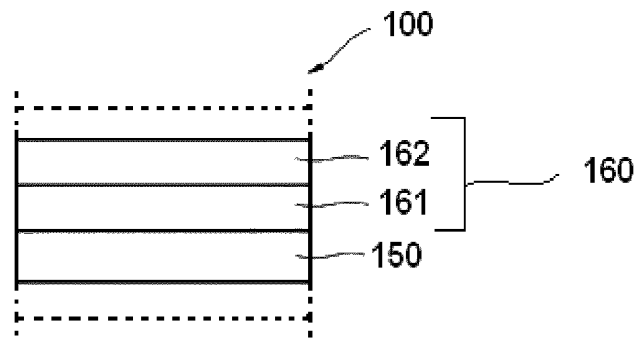


Fig. 1

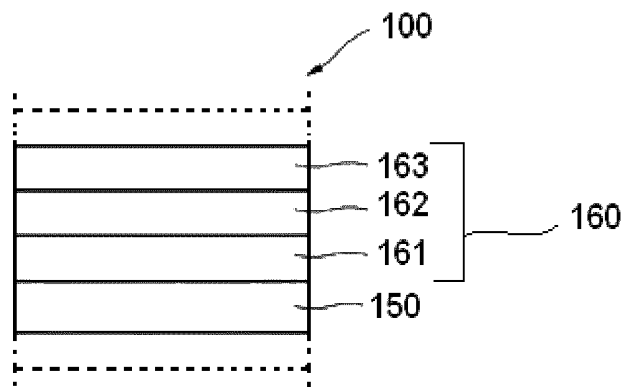


Fig. 2

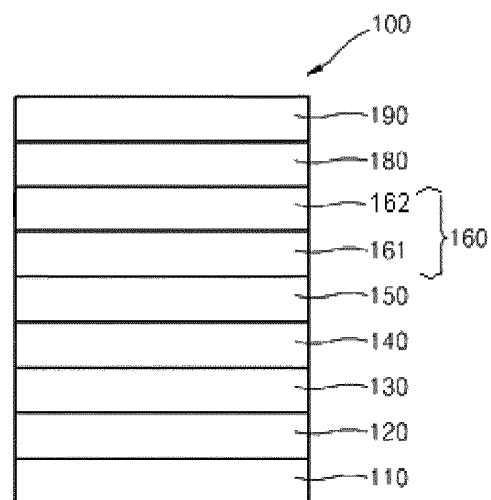


Fig. 3

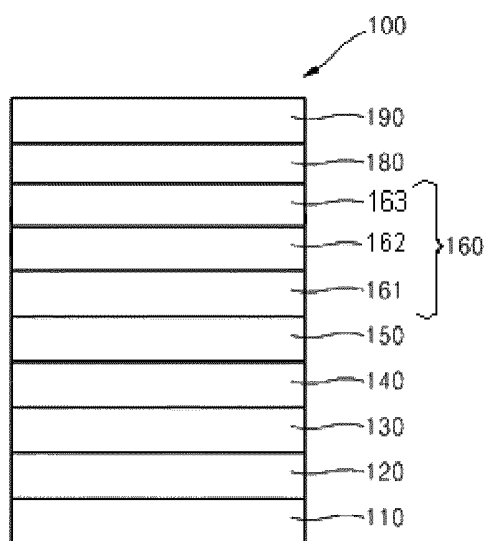


Fig. 4

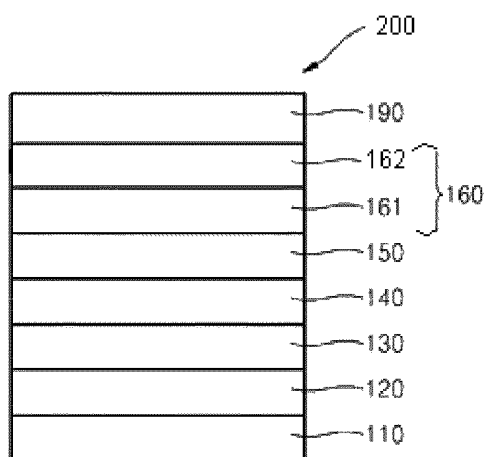


Fig. 5

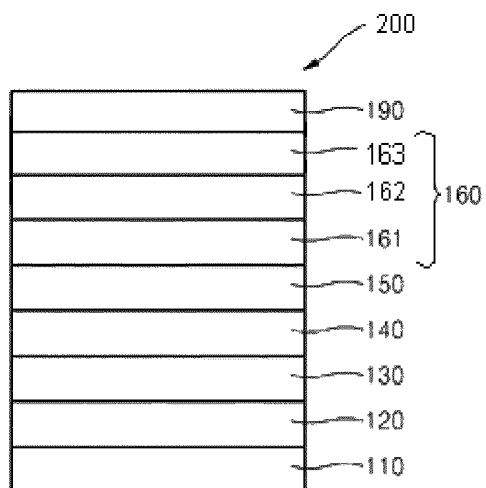


Fig. 6

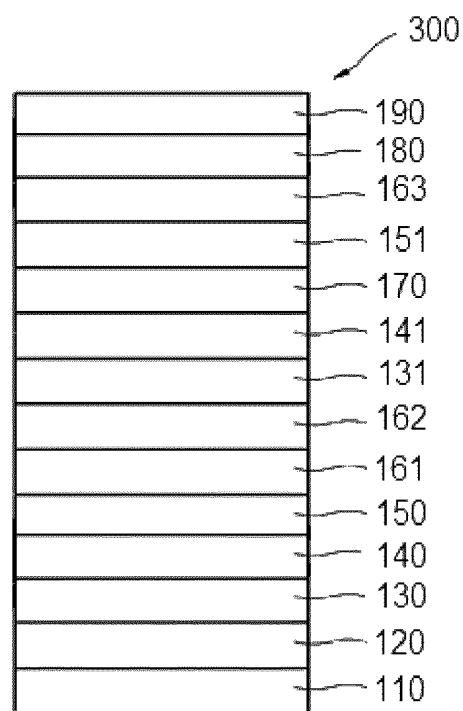


Fig. 7

1

ORGANIC LIGHT-EMITTING DIODE INCLUDING AN ELECTRON TRANSPORT LAYER STACK COMPRISING DIFFERENT LITHIUM COMPOUNDS AND ELEMENTAL METAL

CROSS REFERENCE TO RELATED APPLICATIONS

This application is a U.S. national stage application of PCT/EP2015/071366, filed Sep. 17, 2015, which claims priority to European Application No. 14185560.1, filed Sep. 19, 2014. The contents of these applications are hereby incorporated by reference.

DESCRIPTION

The present invention relates to an organic light-emitting diode including an electron transport layer stack, and a method of manufacturing the same.

DESCRIPTION OF THE RELATED ART

Organic light-emitting diodes (OLEDs), which are self-emitting devices, have a wide viewing angle, excellent contrast, quick response, high brightness, excellent driving voltage characteristics, and color reproduction. A typical OLED includes an anode, a hole transport layer (HTL), an emission layer (EML), an electron transport layer (ETL), and a cathode, which are sequentially stacked on a substrate. In this regard, the HTL, the EML, and the ETL are thin films formed from organic compounds.

When a voltage is applied to the anode and the cathode, holes injected from the anode move to the EML, via the HTL, and electrons injected from the cathode move to the EML, via the ETL. The holes and electrons recombine in the EML to generate excitons. When the excitons drop from an excited state to a ground state, light is emitted. The injection and flow of holes and electrons should be balanced, so that an OLED having the above-described structure has excellent efficiency and/or a long lifetime.

SUMMARY

It is one object to provide organic light-emitting diode having an increased external quantum efficiency (EQE) of OLEDs, especially for blue emitting OLEDs but also, for example for red, green or white, and/or an increased lifetime, in particular for top and/or bottom emission organic light-emitting diodes (OLED).

According to one aspect, there is provided an organic light-emitting diode (OLED) comprising an emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound and in addition,

the at least first electron transport layer comprises a lithium halide or a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or

the at least first electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the at least second electron transport layer comprises a lithium halide or a lithium organic complex;

2

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex.

According to one aspect, there is provided an organic light-emitting diode (OLED) comprising an emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound and in addition,

the at least first electron transport layer comprises a lithium halide or a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or

the at least first electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the at least second electron transport layer comprises a lithium halide or a lithium organic complex;

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex;

wherein the matrix compound of the electron transport layer stack are different for each electron transport layer, except for a phosphine oxide matrix compound. That means the phosphine oxide matrix compound may be same or different selected for each electron transport layer.

In the context that the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, the term "free of" means that the electron transport layer or layers containing lithium halide/organic complex may comprise impurities of about 0.1 wt.-% or less, preferably about 0.01 wt.-% or less, and more preferably about 0.001 wt.-% or less of a metal dopant and most preferred no metal dopant.

In the context that the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex, the term "free of" means that the electron transport layer or layers containing an elemental metal may comprise of about 5 wt.-% or less of a lithium halide and/or a lithium organic complex, preferably about 0.5 wt.-% or less, and more preferably about 0.05 wt.-% or less, and even more preferably about 0.005 wt.-% or less of a lithium halide and/or a lithium organic complex and most preferred no lithium halide and/or a lithium organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound, wherein the matrix compound is a phosphine oxide based compound, preferably selected from the group comprising (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)-(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-

yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide; and in addition,

the at least first electron transport layer comprises a lithium halide or a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or

the at least first electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the at least second electron transport layer comprises a lithium halide or a lithium organic complex;

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound, wherein the first matrix compound is a phosphine oxide based compound, preferably selected from the group comprising (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide; and in addition,

the at least first electron transport layer comprises a lithium halide or a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or

the at least first electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the at least second electron transport layer comprises a lithium halide or a lithium organic complex;

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound, wherein the first matrix compound is a phosphine oxide based compound, preferably selected from the group comprising (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)

phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide; and in addition, the at least first electron transport layer comprises a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound, wherein the first and second matrix compound are independently selected from a phosphine oxide based compound, preferably selected from the group comprising (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide; and in addition, the at least first electron transport layer comprises a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound, wherein the first and second matrix compound is a phosphine oxide based compound, preferably selected from the group comprising (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide; and in addition, the at least first electron transport layer comprises a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium;

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound, wherein the second matrix compound is a phosphine oxide based compound, preferably selected from the group comprising (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide; and in addition,

the at least first electron transport layer comprises a lithium halide or a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or

the at least first electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the at least second electron transport layer comprises a lithium halide or a lithium organic complex;

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound, wherein the second matrix compound is a phosphine oxide based compound, preferably selected from the group comprising (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide; and in addition, the at least first electron transport layer comprises a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium;

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an

elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound and in addition,

the at least first electron transport layer comprises a lithium halide or a lithium organic complex, preferably a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of ytterbium and/or magnesium, preferably ytterbium, in view of the stronger doping effect magnesium can be more preferred; or the at least first electron transport layer comprises an elemental metal selected from the group of ytterbium and/or magnesium, preferably ytterbium; and the at least second electron transport layer comprises a lithium halide or a lithium organic complex, preferably a lithium organic complex;

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound and in addition,

the at least first electron transport layer comprises a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of ytterbium and/or magnesium, preferably ytterbium; or

the at least first electron transport layer comprises an elemental metal selected from the group of ytterbium and/or magnesium, preferably ytterbium; and the at least second electron transport layer comprises a lithium organic complex;

wherein the electron transport layer or layers comprising a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprises at least one matrix compound and in addition,

the at least first electron transport layer comprises a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, ytterbium and/or magnesium, preferably magnesium; or

the at least first electron transport layer comprises an elemental metal selected from the group of lithium, ytterbium and/or magnesium, preferably magnesium; and the at least second electron transport layer comprises a lithium organic complex;

wherein the electron transport layer or layers comprising a lithium organic complex is free of an elemental metal, and

the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex.

According to various aspects, there is provided an organic light-emitting diode comprising at least one emission layer, and an electron transport layer stack of at least three electron transport layers, wherein

at least two electron transport layers comprising a lithium halide or a lithium organic complex; and at least one electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or

at least two electron transport layers comprising an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and at least one electron transport layer comprises a lithium halide or a lithium organic complex;

wherein for an electron transport layer stack comprising at least two electron transport layers comprising a lithium halide or a lithium organic complex the lithium halide or lithium organic complex of each electron transport layer are selected same or different, and preferably different and more preferred selected the same; and/or wherein for an electron transport layer stack comprising at least two electron transport layers comprising an elemental metal selected from the group of lithium, magnesium and/or ytterbium; the elemental metal selected from the group of lithium, magnesium and/or ytterbium of each electron transport layer are selected same or different, and preferably selected the same.

According to various aspects, wherein for an electron transport layer stack comprising at least three electron transport layers, at least one or two electron transport layers comprising a lithium organic complex, the lithium organic complex of each electron transport layer are selected same or different, and preferably the same; and the remaining electron transport layers, comprising an elemental metal selected from the group of lithium, magnesium and/or ytterbium, preferably magnesium and/or ytterbium, wherein each electron transport layer comprising an elemental metal, the elemental metal are selected same or different, and preferably the same.

According to various aspects, wherein for an electron transport layer stack of two electron transport layers the first electron transport layer is arranged closest to at least one emission layer, and the second electron transport layer is arranged closest to a cathode.

According to various aspects, wherein for an electron transport layer stack of three electron transport layers the first electron transport layer is arranged closest to an emission layer, the second electron layer is sandwiched between the first and the third electron transport layer and the third electron transport layer is arranged closest to a cathode.

The organic light-emitting diode can be a bottom emission OLED or a top emission OLED.

For the following defined terms, these definitions shall be applied, unless a different definition is given in the claims or elsewhere in this specification.

The external quantum efficiency, also named EQE, is measured in percent (%).

The lifetime, also named LT, between starting brightness and 97% of the original brightness is measured in hours (h).

The voltage, also named V, is measured in Volt (V) at 10 milliAmpere per square centimeter (mA/cm^2) in bottom emission devices and at 15 mA/cm^2 for top emission devices.

The colour space is described by coordinates CIE-x and CIE-y (International Commission on Illumination 1931).

For blue emission the CIE-y is of particular importance. A smaller CIE-y denotes a deeper blue color.

The efficiency of top emission OLEDs is recorded in candela per Ampere, also named cd/A . Candela is a SI base unit of luminous intensity and describes the power emitted by a light source in a particular direction, weighted by the luminosity function (a standardized model of the sensitivity of the human eye to different wavelengths). The human eye is particularly insensitive to deep blue and deep red colors. Therefore, the efficiency measured in cd/A is corrected for the emission color, in the case of blue emission, the CIE-y. For example, a deeper blue OLED would have a lower cd/A efficiency even if the quantum efficiency (photons in compared to photons out) is the same. By dividing the efficiency measured in cd/A by the CIE-y, the efficiency of OLEDs with slightly different shades of blue can be compared. The efficiency, also named Eff., is measured in Candela per Ampere (cd/A) and divided by the CIE-y.

The highest occupied molecular orbital, also named HOMO, and lowest unoccupied molecular orbital, also named LUMO, are measured in electron volt (eV).

The term "not the same as" with respect to a lithium halide or a lithium organic complex means that the electron transport layers comprising lithium halide or a lithium organic complex, differs in its containing lithium halide or lithium organic complex.

The term "not the same as" with respect to elemental metal selected from the group of lithium, magnesium and/or ytterbium means that the electron transport layers containing elemental lithium, magnesium and/or ytterbium, differs in its containing elemental metal.

The term "OLED" and "organic light-emitting diode" is simultaneously used and having the same meaning.

As used herein, weight percent, "wt.-%", percent by weight, "% by weight", and variations thereof refer to an elemental metal, a composition, component, substance or agent as the weight of that elemental metal, component, substance or agent of the respective electron transport layer divided by the total weight of the respective electron transport layer thereof and multiplied by 100. It is understood that the total weight percent amount of all elemental metal, components, substances or agents of the respective electron transport layer are selected such that it does not exceed 100 wt.-%.

As used herein, volume percent, "vol.-%", percent by volume, "% by volume", and variations thereof refer to an elemental metal, a composition, component, substance or agent as the volume of that elemental metal, component, substance or agent of the respective electron transport layer divided by the total volume of the respective electron transport layer thereof and multiplied by 100. It is understood that the total volume percent amount of all elemental metal, components, substances or agents of the respective electron transport layer are selected such that it does not exceed 100 vol.-%.

All numeric values are herein assumed to be modified by the term "about", whether or not explicitly indicated. As used herein, the term "about" refers to variation in the numerical quantity that can occur. Whether or not modified by the term "about", the claims include equivalents to the quantities.

It should be noted that, as used in this specification and the appended claims, the singular forms "a", "an", and "the" include plural referents unless the content clearly dictates otherwise.

The term “free of”, “does not contain”, “does not comprise” does not exclude impurities. Impurities have no technical effect with respect to the object achieved by the present invention.

The cathode is not an electron transport layer or electron layer stack. In particular the second electron transport layer is not a cathode. According to the present invention the cathode and the electron transport layer differs in their chemical composition.

Further, the electron layer stack is arranged between the anode and cathode layer.

Further, for reasons of clarification, the electron transport layer differs in their chemical composition from the cathode described in EP 2 075 858 A1.

The term “alkyl” refers to straight-chain or branched alkyl groups. The term “1 to 20 carbon atoms” as used herein refers to straight-chain or branched alkyl groups having 1 to 20 carbon atoms. The alkyl groups can be selected from the group comprising methyl, ethyl and the isomers of propyl, butyl or pentyl, such as isopropyl, isobutyl, tert.-butyl, sec.-butyl and/or isopentyl. The term “aryl” refers to aromatic groups for example phenyl or naphthyl.

Herein, when a first element is referred to as being formed or disposed “on” a second element, the first element can be disposed directly on the second element or one or more other elements may be disposed there between. When a first element is referred to as being formed or disposed “directly on” a second element, no other elements are disposed there between.

According to various embodiments of the OLED, the electron transport layer stack wherein at least one electron transport layer may be free of a lithium halide or all electron transport layers may be free of a lithium halide.

According to various embodiments of the OLED the electron transport layer stack may comprise as a lithium compound a lithium organic complex only.

According to various embodiments of the organic light-emitting diode the amount of the lithium halide or lithium organic complex in an electron transport layer stack, preferably the at least first electron transport layer, is in the range of about ≥ 10 mol-% to about ≤ 95 mol-%, preferably about ≥ 15 mol-% to about ≤ 90 mol-% and also preferred about ≥ 20 mol-% to about ≤ 80 mol-%, of the corresponding electron transport layer; and/or the amount of the lithium halide or lithium organic complex in an electron transport layer stack of at least three electron transport layers, at least two of the electron transport layers, preferably the at least first electron transport layer and/or the at least third electron transport layer, is in the range of about ≥ 10 mol-% to about ≤ 95 mol-%, preferably about ≥ 15 mol-% to about ≤ 90 mol-% and also preferred about ≥ 20 mol-% to about ≤ 80 mol-%, of the corresponding electron transport layer.

According to various embodiments of the OLED of the present invention the lithium halide or lithium halide can be selected from the group comprising LiF, LiCl, LiBr and LiI. However, most preferred is LiF.

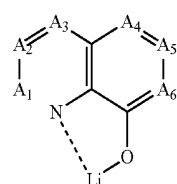
According to various embodiments of the organic light-emitting diode comprising an electron transport layer stack, preferably of at least two electron transport layer or three electron transport layer, wherein

at least one electron transport layer, comprises about ≥ 1 wt.-% to about ≤ 60 wt.-%, preferably about ≥ 2 wt.-% to about ≤ 55 wt.-% and also preferred about ≥ 5 wt.-% to about ≤ 45 wt.-% of an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or at least two electron transport layer (161/163) of at least three electron transport layers (161/162/163) comprises

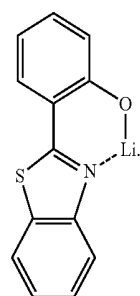
about ≥ 1 wt.-% to about ≤ 60 wt.-%, preferably about ≥ 2 wt.-% to about ≤ 55 wt.-% and also preferred about ≥ 5 wt.-% to about ≤ 45 wt.-% of an elemental metal selected from the group of lithium, magnesium and/or ytterbium;

wherein the weight percent of the elemental metal selected from the group of lithium, magnesium and/or ytterbium is based on the total weight of the corresponding electron transport layer.

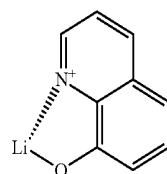
According to various embodiments of the organic light-emitting diode (OLED) of the present invention the organic ligand of the lithium organic complex can be a quinolate. Preferably the lithium organic complex is a lithium organic complex of formula I, II or III:



(I)



(II)



(III)

wherein

A1 to A6 are same or independently selected from CH, CR, N, O;

R is same or independently selected from hydrogen, halogen, alkyl or aryl or heteroaryl with 1 to 20 carbon atoms; and more preferred A1 to A6 are CH.

Quinolates that can be suitable used are disclosed in WO 2013079217 A1 and incorporated by reference.

According to various embodiments of the organic light-emitting diode (OLED) of the present invention the organic ligand of the lithium organic complex can be a borate based organic ligand, Preferably the lithium organic complex is a lithium tetra(1H-pyrazol-1-yl)borate. Borate based organic ligands that can be suitable used are disclosed in WO 2013079676 A1 and incorporated by reference.

According to various embodiments of the organic light-emitting diode (OLED) of the present invention the organic ligand of the lithium organic complex can be a phenolate ligand, Preferably the lithium organic complex is a lithium 2-(diphenylphosphoryl)phenolate. Phenolate ligands that can be suitable used are disclosed in WO 2013079678 A1 and incorporated by reference.

Further, phenolate ligands can be selected from the group of pyridinolate, preferably 2-(diphenylphosphoryl)pyridin-

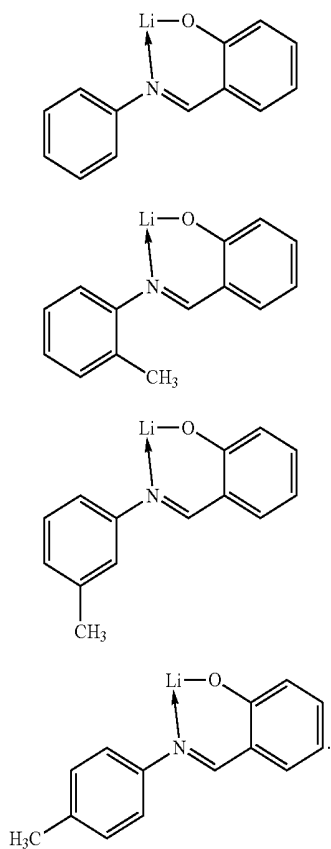
11

3-olate. Pyridine phenolate ligands that can be suitable used are disclosed in JP 2008195623 and incorporated by reference.

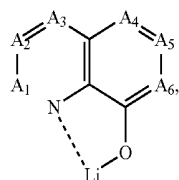
In addition, phenolate ligands can be selected from the group of imidazol phenolates, preferably 2-(1-phenyl-1H-benzo[d]imidazol-2-yl)phenolate. Imidazol phenolate ligands that can be suitable used are disclosed in JP 2001291593 and incorporated by reference.

Also, phenolate ligands can be selected from the group of oxazol phenolates, preferably 2-(benzo[d]oxazol-2-yl)phenolate. Oxazol phenolate ligands that can be suitable used are disclosed in US 20030165711 and incorporated by reference.

Lithium Schiff base organic complexes can be used. Lithium Schiff base organic complexes that can be suitable used having the structure 100, 101, 102 or 103:

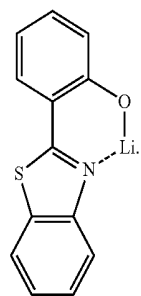


According to various embodiments of the organic light-emitting diode (OLED) of the present invention the organic ligand of the lithium organic complex is a quinolate, a borate, a phenolate, a pyridinolate or a Schiff base ligand; preferably the lithium quinolate complex has the formula I, II or III:

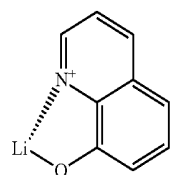


12

-continued



(II)



(III)

wherein

A1 to A6 are same or independently selected from CH, CR, N, O;

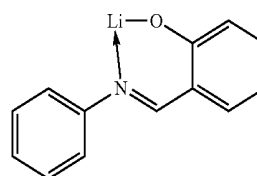
R is same or independently selected from hydrogen, halogen, alkyl or aryl or heteroaryl with 1 to 20 carbon atoms; and more preferred A1 to A6 are CH;

preferably the borate based organic ligand is a tetra(1H-pyrazol-1-yl)borate;

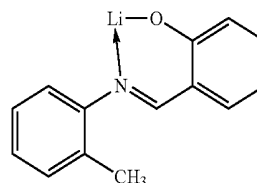
preferably the phenolate is a 2-(pyridin-2-yl)phenolate, a 2-(diphenylphosphoryl)-phenolate, an imidazol phenolates, or 2-(pyridin-2-yl)phenolate and more preferred 2-(1-phenyl-1H-benzo[d]imidazol-2-yl)phenolate;

preferably the pyridinolate is a 2-(diphenylphosphoryl)pyridin-3-olate,

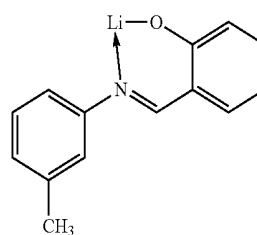
preferably the lithium Schiff base has the structure 100, 101, 102 or 103:



100



101



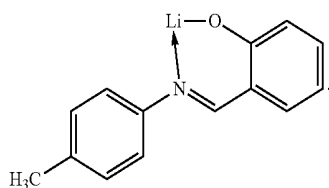
102

(I)

65

13

-continued



According to various embodiments of the organic light-emitting diode (OLED) of the present invention the first electron transport layer, the second electron transport layer and/or in case of three electron transport layers the third electron transport layer as well, may comprises at least one matrix compound each.

According to various embodiments of the organic light-emitting diode (OLED) of the present invention comprising an electron transport layer stack of at least two electron transport layers or at least three electron transport layers, wherein each electron transport layer comprises at least one matrix compound, whereby the matrix compound of the electron transport layers are selected same or different.

According to various embodiments of the organic light-emitting diode (OLED) the at least two electron transport layers (161/162) or the at least three electron transport layers (161/162/163) comprise at least one matrix compound, whereby the matrix compound of the electron transport layers are selected same or different, and wherein the electron matrix compound is selected from:

an anthracene based compound or a heteroaryl substituted anthracene based compound, preferably 2-(4-(9,10-di(naphthalen-2-yl)anthracene-2-yl)phenyl)-1-phenyl-1H-benzo[d]imidazole, 1-(4-(10-([1,1'-biphenyl]-4-yl)anthracen-9-yl)phenyl)-2-ethyl-1H-benzo[d]imidazole and/or N4,N4"-di(naphthalen-1-yl)-N4,N4"-diphenyl-[1,1':4',1"-terphenyl]-4,4"-diamine;

a phosphine oxide based compound, preferably (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, phenyl bis (3-(pyren-1-yl)phenyl)phosphine oxide, 3-Phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide;

a substituted phenanthroline compound, preferably 2,4,7,9-tetraphenyl-1,10-phenanthroline, 4,7-diphenyl-2,9-di-p-tolyl-1,10-phenanthroline and/or 2,9-di(biphenyl-4-yl)-4,7-diphenyl-1,10-phenanthroline.

According to various embodiments of the organic light-emitting diode (OLED) of the present invention the thicknesses of each electron transport layer, preferably the at least first electron transport layer (161) and the at least second electron transport layer (162) and/or the at least third electron transport layer (163), are same or each independently, in the range of about ≥ 0.5 nm to about ≤ 95 nm, preferably of about ≥ 3 nm to about ≤ 80 nm, further preferred of about ≥ 5 nm to about ≤ 60 nm, also preferred of about ≥ 6 nm to about ≤ 40 nm, in addition preferred about ≥ 8 nm to about ≤ 20 nm and more preferred of about ≥ 10 nm to about ≤ 18 nm.

14

According to various embodiments of the organic light-emitting diode (OLED) the thicknesses of the electron transport layer stack can be in the range of about ≥ 25 nm to about ≤ 100 nm, preferably of about ≥ 30 nm to about ≤ 80 nm, further preferred of about ≥ 35 nm to about ≤ 60 nm, and more preferred of about ≥ 36 nm to about ≤ 40 nm.

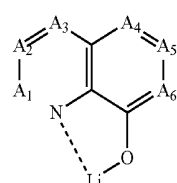
According to various embodiments of the organic light-emitting diode (OLED) of the present invention the electron transport layer stack has 2 to 4 electron transport layers and more preferred 2 to 3 electron transport layers.

According to various embodiments of the organic light-emitting diode (OLED) of the present invention the second electron transport layer can be formed directly on the first electron transport layer and an optional third electron transport layer can be formed directly on the second electron transport layer, so that the second electron transport layer is sandwiched between the first and third electron transport layers.

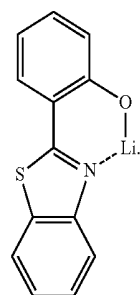
According to various embodiments of the organic light-emitting diode (OLED) of the present invention:

at least one electron transport layer or in case of at least three electron transport layers at least two electron transport layer comprise:

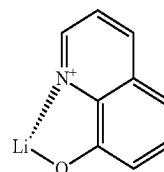
a) about ≥ 10 wt.-% to about ≤ 70 wt.-%, preferably about ≥ 20 wt.-% to about ≤ 65 wt.-% and also preferred about ≥ 50 wt.-% to about ≤ 60 wt.-% of a lithium halide, selected from the group comprising a LiF, LiCl, LiBr or LiI, preferably LiF, or of a lithium organic complex of a lithium quinolate, a borate, a phenolate, a pyridinolate or a Schiff base ligand; preferably of a lithium quinolate complex has the formula I, II or III:



(I)



(II)



(III)

wherein

A1 to A6 are same or independently selected from CH, CR, N, O,

R is same or independently selected from hydrogen, halogen, alkyl or aryl or heteroaryl with 1 to 20 carbon atoms, and more preferred of a lithium 8-hydroxyquinolate;

b) about ≤ 90 wt.-% to about ≥ 30 wt.-%, preferably about ≤ 80 wt.-% to about ≥ 35 wt.-% and also preferred about ≤ 50 wt.-% to about ≥ 40 wt.-% and also preferred about ≤ 50 wt.-% to about ≥ 40 wt.-% of a matrix compound of: an anthracene based compound or a heteroaryl substituted anthracene based compound, preferably 2-(4-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)-1-phenyl-1H-benzo[d]imidazole, 1-(4-(10-([1,1'-biphenyl]-4-yl)anthracen-9-yl)phenyl)-2-ethyl-1H-benzo[d]imidazole and/or N4,N4"-di(naphthalen-1-yl)-N4,N4"-diphenyl-[1,1':4',1"-terphenyl]-4,4"-diamine;

a phosphine oxide based compound, preferably (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide;

a substituted phenanthroline compound, preferably 2,4,7,9-tetraphenyl-1,10-phenanthroline, 4,7-diphenyl-2,9-di-p-tolyl-1,10-phenanthroline and/or 2,9-di(biphenyl-4-yl)-4,7-diphenyl-1,10-phenanthroline;

whereby more preferred is a phosphine oxide based compound and most preferred is (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide; and

at least one electron transport layer or in case of at least three electron transport layers at least two electron layers comprising:

c) about ≥ 1 wt.-% to about ≤ 60 wt.-%, preferably about ≥ 2 wt.-% to about ≤ 55 wt.-% and also preferred about ≥ 5 wt.-% to about ≤ 45 wt.-% of an elemental metal selected from the group of lithium, magnesium and/or ytterbium, more preferred of an elemental metal magnesium;

d) about ≤ 99 wt.-% to about ≥ 40 wt.-%, preferably about ≤ 98 wt.-% to about ≥ 45 wt.-% and also preferred about ≤ 95 wt.-% to about ≥ 55 wt.-% of a matrix compound of: an anthracene based compound or a heteroaryl substituted anthracene based compound, preferably 2-(4-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)-1-phenyl-1H-benzo[d]imidazole, 1-(4-(10-([1,1'-biphenyl]-4-yl)anthracen-9-yl)phenyl)-2-ethyl-1H-benzo[d]imidazole and/or N4,N4"-di(naphthalen-1-yl)-N4,N4"-diphenyl-[1,1':4',1"-terphenyl]-4,4"-diamine;

a phosphine oxide based compound, preferably (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide and/or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide;

a substituted phenanthroline compound, preferably 2,4,7,9-tetraphenyl-1,10-phenanthroline, 4,7-diphenyl-2,9-

di-p-tolyl-1,10-phenanthroline and/or 2,9-di(biphenyl-4-yl)-4,7-diphenyl-1,10-phenanthroline;

wherein more preferred is a phosphine oxide based compound and most preferred is (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide;

wherein the weight percent of each component is based on the total weight of the corresponding electron transport layer.

According to various embodiments of the OLED of the present invention:

the at least one, preferably two, lithium organic complex containing electron transport layer (161) comprises of about ≥ 50 wt.-% to about ≤ 60 wt.-% of a lithium 8-hydroxyquinolate and about ≤ 50 wt.-% to about ≥ 40 wt.-% of a (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide; and

the at least one, preferably two, elemental metal containing electron transport layer (162) comprises of about ≥ 2 wt.-% to about ≤ 45 wt.-% of an elemental metal selected from the group of lithium, magnesium and/or ytterbium, more preferred of an elemental metal magnesium and about ≤ 98 wt.-% to about ≥ 55 wt.-% of a (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide.

According to another aspect, there is provided an organic light-emitting diode comprising: a substrate; a first anode electrode formed on the substrate; a second cathode electrode formed on the first anode electrode; and an electron transport layer stack arranged between the first anode electrode and the second cathode electrode, comprising or consisting of at least two electron transport layers or at least three electron transport layers.

According to various embodiments, the organic light-emitting diode (OLED) may further include at least one layer selected from the group consisting of a hole injection layer, a hole transport layer, an emission layer, and a hole blocking layer, arranged between the first anode electrode and the electron transport layer.

According to another aspect, there is provided an organic light-emitting diode comprising in addition: at least one layer selected from the group consisting of a hole injection layer, a hole transport layer, an emission layer, and a hole blocking layer, arranged between the first anode electrode and the electron transport layer stack.

According to various aspects, there is provided an organic light-emitting diode further comprising an electron injection layer arranged between the electron transport layer and the second cathode electrode.

According to various embodiments of the OLED of the present invention, the OLED may not comprise an electron injection layer.

According to another aspect, there is provided a method of manufacturing an organic light-emitting diode (OLED), the method using:

deposition via at least three deposition sources; or deposition via vacuum thermal evaporation; or deposition via solution processing, preferably the processing is selected from spin-coating, printing, casting and/or slot-die coating.

According to various aspects, there is provided a method using:

at least one or two deposition sources to release the matrix compound, and

at least one or two deposition sources to release lithium halide or lithium organic complex, and

17

at least at least one or two deposition sources to release the elemental metal; the method comprising the steps of forming the electron transport layer stack; whereby a first electron transport layer is formed by releasing the matrix compound from at least one deposition source and a lithium halide or a lithium organic complex or an elemental metal is released from at different deposition source;

onto the first electron transport layer a second electron transport layer is formed by releasing the matrix compound from at least one deposition source and a lithium halide or a lithium organic complex or an elemental metal is released from at different deposition source; onto the second electron transport layer a third electron transport layer is formed by releasing the matrix compound from at least one deposition source and a lithium halide or a lithium organic complex or an elemental metal is released from at different deposition source; whereby

at least one electron transport layer comprises a lithium halide or a lithium organic complex and is free of an elemental metal; and at least one electron transport layer comprises an elemental metal and is free of a lithium halide or a lithium organic complex.

According to various aspects, the method may further include forming on the first anode electrode at least one emission layer, and at least one layer selected from the group consisting of forming a hole injection layer, forming a hole transport layer, or forming a hole blocking layer, between the first anode electrode and the electron transport layer stack.

According to various aspects, the method may further include the steps for forming an organic light-emitting diode (OLED), wherein

on a substrate a first anode electrode is formed, on the first anode electrode an emission layer is formed, on the emission layer an electron transport layer stack is formed, comprising at least two, or at least three electron transport layers, preferably the first electron transport layer is formed on the emission layer and the second electron transport layer or, in case of a third electron transport layer, the third electron transport layer is formed directly on the first electron transport layer,

on the electron transport layer stack a second cathode electrode is formed,

optional a hole injection layer, a hole transport layer, and a hole blocking layer, formed in that order between the first anode electrode and the emission layer,

optional an electron injection layer is arranged between the electron transport layer and the second cathode electrode.

According to various aspects, the method may further include forming an electron injection layer on the electron transport layer stack.

Additional aspects and/or advantages of the invention will be set forth in part in the description which follows and, in part, will be obvious from the description, or may be learned by practice of the invention.

BRIEF DESCRIPTION OF THE DRAWINGS

These and/or other aspects and advantages of the present invention will become apparent and more readily appreciated from the following description of the exemplary embodiments, taken in conjunction with the accompanying drawings, of which:

18

FIG. 1 is a schematic sectional view of an organic light-emitting diode (OLED), according to an exemplary embodiment of the present invention with two electron transport layers;

FIG. 2 is a schematic sectional view of an OLED, according to an exemplary embodiment of the present invention with three electron transport layers;

FIG. 3 is a schematic sectional view of an organic light-emitting diode (OLED), according to an exemplary embodiment of the present invention with two electron transport layers;

FIG. 4 is a schematic sectional view of an OLED, according to an exemplary embodiment of the present invention with three electron transport layers;

FIG. 5 is a schematic sectional view of an OLED, according to an exemplary embodiment of the present invention with two electron transport layers and having no electron injection layer (EIL);

FIG. 6 is a schematic sectional view of an OLED, according to an exemplary embodiment of the present invention with three electron transport layers and having no electron injection layer (EIL);

FIG. 7 is a schematic sectional view of a tandem OLED, according to an exemplary embodiment of the present invention.

DETAILED DESCRIPTION

Reference will now be made in detail to the exemplary aspects, examples of which are illustrated in the accompanying drawings, wherein like reference numerals refer to the like elements throughout. The exemplary embodiments are described below, in order to explain the aspects, by referring to the figures.

Herein, when a first element is referred to as being formed or disposed "on" a second element, the first element can be disposed directly on the second element, or one or more other elements may be disposed there between. When a first element is referred to as being formed or disposed "directly on" a second element, no other elements are disposed there between.

FIG. 1 is a schematic sectional view of an organic light-emitting diode 100, according to an exemplary embodiment of the present invention. The OLED 100 includes an emission layer 150 and an electron transport layer stack (ETL) 160 comprising a first electron transport layer 161 and a second electron transport layer 162, whereby the second electron transport layer 162 is disposed directly on the first electron transport layer 161.

FIG. 2 is a schematic sectional view of an organic light-emitting diode 100, according to an exemplary embodiment of the present invention. The OLED 100 includes an emission layer 150 and an electron transport layer stack (ETL) 160 comprising a first electron transport layer 161, a second electron transport layer 162, and a third electron transport layer 163, whereby the second electron transport layer 162 is disposed directly on the first electron transport layer 161 and the third electron transport layer 163 is disposed directly on the first electron transport layer 162.

FIG. 3 is a schematic sectional view of an organic light-emitting diode 100, according to an exemplary embodiment of the present invention. The OLED 100 includes a substrate 110, a first electrode 120, a hole injection layer (HIL) 130, a hole transport layer (HTL) 140, an emission layer (EML) 150, an electron transport layer (ETL) 160, an electron injection layer (EIL) 180, and a second electrode 190. The electron transport layer (ETL) 160

includes a first electron transport layer **161** including a matrix material and a lithium halide or a lithium organic complex and a second electron transport layer **162** including an elemental metal selected from the group comprising of lithium, magnesium and/or ytterbium. The second electron transport layer **162** is directly formed on the first electron transport layer **161**. The first layer **161** may be formed directly on the EML **150**.

FIG. 4 is a schematic sectional view of an organic light-emitting diode **100**, according to an exemplary embodiment of the present invention. The OLED **100** includes a substrate **110**, a first electrode **120**, a hole injection layer (HIL) **130**, a hole transport layer (HTL) **140**, an emission layer (EML) **150**, an electron transport layer (ETL) **160**, an electron injection layer (EIL) **180**, and a second electrode **190**. The electron transport layer (ETL) **160** includes a first electron transport layer **161** and a third electron transport layer **163** including a matrix material and a lithium halide or a lithium organic complex, wherein the lithium halide or the lithium organic complex of the first electron transport layer **161** is not the same as the lithium halide or the lithium organic complex of the third electron transport layer **163**; and the second electron transport layer **162** including an elemental metal of lithium, magnesium and/or ytterbium. The second electron transport layer **162** is directly formed on the first electron transport layer **161** and the third electron layer **163** is directly formed on the second electron layer **162**. The first layer **161** may be formed directly on the emission layer (EML) **150**.

The substrate **110** may be any substrate that is commonly used in manufacturing of organic light-emitting diodes. If light is emitted through the substrate, the substrate **110** may be a transparent material, for example a glass substrate or a transparent plastic substrate, having excellent mechanical strength, thermal stability, transparency, surface smoothness, ease of handling, and waterproofness. If light is emitted through the top surface, the substrate **110** may be a transparent or non-transparent material, for example a glass substrate, a plastic substrate, a metal substrate or a silicon substrate.

The first anode electrode **120** may be formed by depositing or sputtering a compound that is used to form the first anode electrode **120**. The compound used to form the first anode electrode **120** may be a high work-function compound, so as to facilitate hole injection. If a p-doped HIL is used, the anode material may also be selected from a low work function material (i.e. Aluminum). The first anode electrode **120** may be a transparent or reflective electrode. Transparent conductive compounds, such as indium tin oxide (ITO), indium zinc oxide (IZO), tin-dioxide (SnO₂), and zinc oxide (ZnO), may be used to form the first anode electrode **120**. The first anode electrode **120** may also be formed using magnesium (Mg), aluminum (Al), aluminum-lithium (Al—Li), calcium (Ca), magnesium-indium (Mg—In), magnesium-silver (Mg—Ag), silver (Ag), gold (Au), or the like.

The HIL **130** may be formed on the first anode electrode **120** by vacuum deposition, spin coating, printing, casting, slot-die coating, Langmuir-Blodgett (LB) deposition, or the like. When the HIL **130** is formed using vacuum deposition, the deposition conditions may vary according to the compound that is used to form the HIL **130**, and the desired structure and thermal properties of the HIL **130**. In general, however, conditions for vacuum deposition may include a deposition temperature of 100° C. to 500° C., a pressure of 10⁻⁸ to 10⁻³ Torr (1 Torr equals 133.322 Pa), and a deposition rate of 0.1 to 10 nm/sec.

When the HIL **130** is formed using spin coating, printing, coating conditions may vary according to a compound that is used to form the HIL **130**, and the desired structure and thermal properties of the HIL **130**. For example, the coating conditions may include a coating speed of about 2000 rpm to about 5000 rpm, and a thermal treatment temperature of about 80° C. to about 200° C. Thermal treatment removes a solvent after the coating is performed.

The HIL **130** may be formed of any compound that is commonly used to form an HIL. Examples of compounds that may be used to form the HIL **130** include a phthalocyanine compound, such as copper phthalocyanine (CuPc), 4,4',4''-tris(3-methylphenylphenylamino) triphenylamine (m-MTDATA), TDATA, 2T-NATA, polyaniline/dodecylbenzenesulfonic acid (Pani/DBSA), poly(3,4-ethylenedioxythiophene)/poly(4-styrenesulfonate) (PEDOT/PSS), polyaniline/camphor sulfonic acid (Pani/CSA), and polyaniline/poly(4-styrenesulfonate) (PANI/PSS).

The HIL **130** may be a pure layer of p-dopant or may be selected from a hole-transporting matrix compound doped with a p-dopant. Typical examples of known redox doped hole transport materials are: copper phthalocyanine (CuPc), which HOMO level is approximately -5.2 eV, doped with tetrafluoro-tetracyanoquinonodimethane (F4TCNQ), which LUMO level is about -5.2 eV; zinc phthalocyanine (ZnPc) (HOMO=-5.2 eV) doped with F4TCNQ; α -NPD (N,N-Bis(naphthalen-1-yl)-N,N-bis(phenyl)-benzidine) doped with F4TCNQ. α -NPD doped with 2,2'-(perfluoronaphthalene-2,6-diylidene)dimalononitrile (PD1). α -NPD doped with 2,2',2''-(cyclopropane-1,2,3-triylidene)tris(2-(p-cyanotetrafluorophenyl)acetonitrile) (PD2). Dopant concentrations can be selected from 1 to 20 wt.-%, more preferably from 3 wt.-% to 10 wt.-%.

The thickness of the HIL **130** may be in the range of about 1 nm to about 100 nm, and for example, about 1 nm to about 25 nm. When the thickness of the HIL **130** is within this range, the HIL **130** may have excellent hole injecting characteristics, without a substantial increase in driving voltage.

The hole transport layer (HTL) **140** may be formed on the HIL **130** by vacuum deposition, spin coating, slot-die coating, printing, casting, Langmuir-Blodgett (LB) deposition, or the like. When the HTL **140** is formed by vacuum deposition or spin coating, the conditions for deposition and coating may be similar to those for the formation of the HIL **130**. However, the conditions for the vacuum or solution deposition may vary, according to the compound that is used to form the HTL **140**.

The HTL **140** may be formed of any compound that is commonly used to form a HTL. Compound that can be suitably used is disclosed for example in Yasuhiko Shirota and Hiroshi Kageyama, Chem. Rev. 2007, 107, 953-1010 and incorporated by reference. Examples of the compound that may be used to form the HTL **140** are: a carbazole derivative, such as N-phenylcarbazole or polyvinylcarbazole; an amine derivative having an aromatic condensation ring, such as N,N-bis(3-methylphenyl)-N,N-diphenyl-[1,1'-biphenyl]-4,4'-diamine (TPD), or N,N'-di(naphthalene-1-yl)-N,N'-diphenyl benzydine (α -NPD); and a triphenylamine-based compound, such as 4,4',4''-tris(N-carbazolyl)triphenylamine (TCTA). Among these compounds, TCTA can transport holes and inhibit excitons from being diffused into the EML.

The thickness of the HTL **140** may be in the range of about 5 nm to about 250 nm, preferably, about 10 nm to about 200 nm, further about 20 nm to about 190 nm, further about 40 nm to about 180 nm, further about 60 nm to about

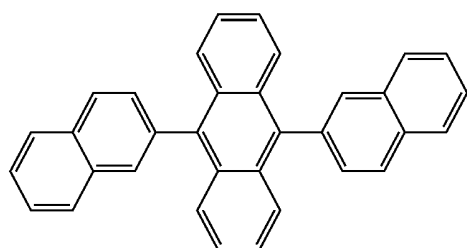
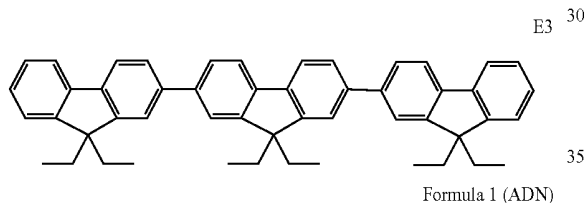
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170 nm, further about 80 nm to about 160 nm, further about 100 nm to about 160 nm, further about 120 nm to about 140 nm. A preferred thickness of the HTL **140** may be 170 nm to 200 nm.

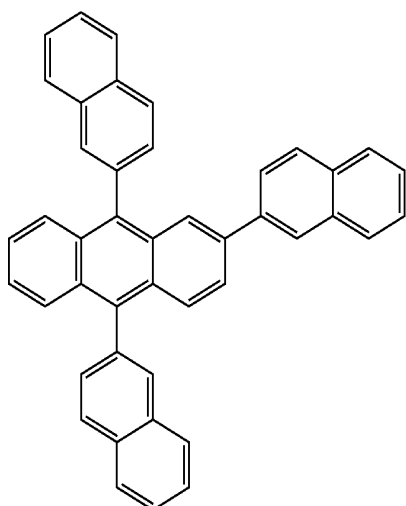
When the thickness of the HTL **140** is within this range, the HTL **140** may have excellent hole transporting characteristics, without a substantial increase in driving voltage.

The EML **150** may be formed on the HTL **140** by vacuum deposition, spin coating, slot-die coating, printing, casting, LB, or the like. When the EML **150** is formed using vacuum deposition or spin coating, the conditions for deposition and coating may be similar to those for the formation of the HIL **130**. However, the conditions for deposition and coating may vary, according to the compound that is used to form the EML **150**.

The emission layer (EML) **150** may be formed of a combination of a host and a dopant. Example of the host are Alq₃, 4,4'-N,N'-dicarbazole-biphenyl (CBP), poly(n-vinylcarbazole) (PVK), 9,10-di(naphthalene-2-yl)anthracene (ADN), TCTA, 1,3,5-tris(N-phenylbenzimidazole-2-yl)benzene (TPBI), 3-tert-butyl-9,10-di-2-naphthylanthracene (TBADN), distyrylarylene (DSA), Bis(2-(2-hydroxyphenyl)benzothiazolate)zinc (Zn(BTZ)₂), E3 below, ADN and referred to as Formula 1, Compound 1 below, and Compound 2 below.



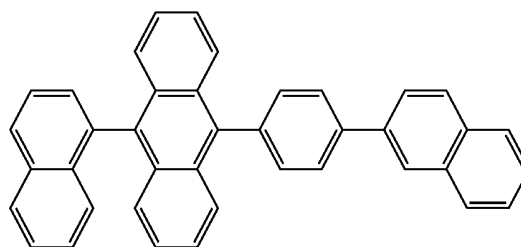
Compound 1



22

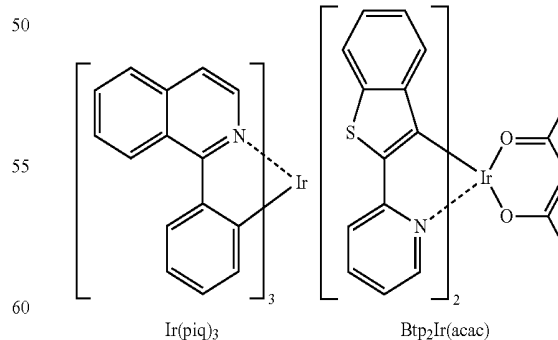
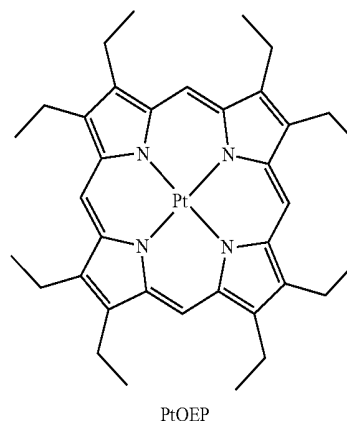
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Compound 2



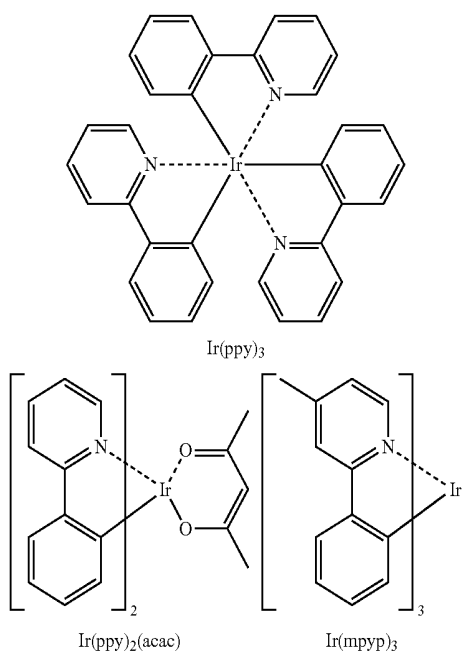
The dopant may be a phosphorescent or fluorescent emitter. Phosphorescent emitters are preferred due to their higher efficiency

Examples of a red dopant are PtOEP, Ir(piq)₃, and Btp 2Ir(acac), but are not limited thereto. These compounds are phosphorescent emitters, however, fluorescent red dopants could also be used.



Examples of a phosphorescent green dopant are Ir(ppy)₃ (ppy=phenylpyridine), Ir(ppy)₂(acac), Ir(mppy)₃ are shown below. Compound 3 is an example of a fluorescent green emitter and the structure is shown below.

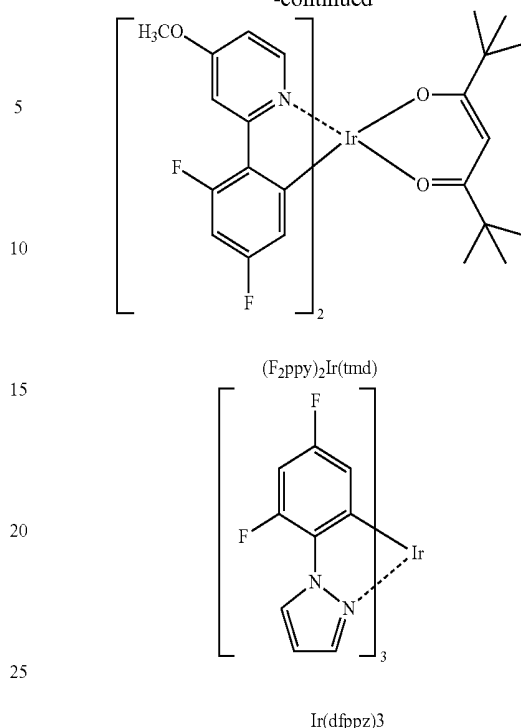
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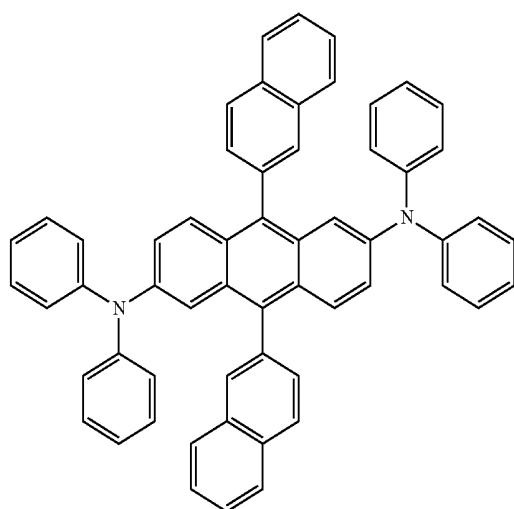
Compound 3

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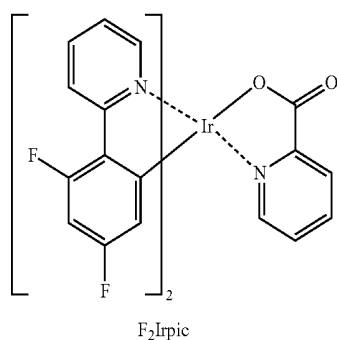
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Compound 4



Examples of a phosphorescent blue dopant are F₂Irpic, (F₂ppy)₂Ir(tmd) and Ir(dfppz) 3, ter-fluorene, the structures are shown below. 4,4'-bis(4-diphenyl amino)styryl)biphenyl (DPAVBi), 2,5,8,11-tetra-tert-butyl perylene (TBPe), and Compound 4 below are examples of fluorescent blue dopants.



The amount of the dopant may be in the range of about 0.01 to about 50 parts by weight, based on 100 parts by weight of the host. The EML 150 may have a thickness of about 10 nm to about 100 nm, for example, about 20 nm to about 60 nm. When the thickness of the EML 150 is within this range, the EML 150 may have excellent light emission, without a substantial increase in driving voltage.

When the EML 150 comprises a phosphorescent dopant, a hole blocking layer (HBL) (not shown) may be formed on the EML 150, by using vacuum deposition, spin coating, slot-die coating, printing, casting, LB deposition, or the like, in order to prevent the diffusion of triplet excitons or holes into the ETL 160. When the HBL is formed using vacuum deposition or spin coating, the conditions for deposition and coating may be similar to those for the formation of the HIL 130. However, the conditions for deposition and coating may vary, according to the compound that is used to form the HBL. Any compound that is commonly used to form a HBL may be used. Examples of compounds for forming the HBL include an oxadiazole derivative, a triazole derivative, and a phenanthroline derivative.

The HBL may have a thickness of about 5 nm to about 100 nm, for example, about 10 nm to about 30 nm. When the

25

thickness of the HBL is within this range, the HBL may have excellent hole-blocking properties, without a substantial increase in driving voltage.

The ETL **160** may be formed on the EML **150** or on the HBL if the HBL is formed. The ETL **160** includes a first layer **161** including a lithium halide or a lithium organic complex; and the second electron transport layer **162** comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or vice versa.

The ETL **160** has a stacked structure, preferably of two ETL-layers (**161/162**), so that injection and transport of electrons may be balanced and holes may be efficiently blocked. In a conventional OLED, since the amounts of electrons and holes vary with time, after driving is initiated, the number of excitons generated in an emission area may be reduced. As a result, a carrier balance may not be maintained, so as to reduce the lifetime of the OLED.

However, in the ETL **160**, the first layer **161** and the second layer **162** may have similar or identical energy levels. Surprisingly, it was found that the lifetime (LT) of the OLED **100** is improved irrespective of HOMO level of the matrix compounds.

In general the matrix compound for the first electron layer (**161**) and second electron layer (**162**) can be identical or different.

Matrix compound for the first electron layer (**161**) and second electron layer (**162**) that can be suitably used are selected from the group comprising anthracene compounds, preferably 2-(4-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)-1-phenyl-1H-benzo[d]imidazole.

Anthracene compounds that can be used as matrix materials are disclosed in U.S. Pat. No. 6,878,469 B and incorporated by reference.

Other matrix compounds that can be used are diphenylphosphine oxide, preferably (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, phenylbis (3-(pyren-1-yl)phenyl) phosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho [2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl) (phenyl)phosphine oxide, phenyldi(pyren-1-yl) phosphine oxide.

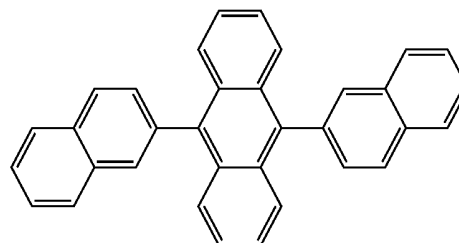
Diphenylphosphine oxide compounds that can be used as matrix materials are disclosed in EP 2395571 A1, WO2013079217 A1, EP 13187905, EP13199361 and JP2002063989 A1, incorporated by reference. Other suitable matrix compounds that can be used are phenanthroline compounds, preferably selected from the group comprising of 2,4,7,9-tetraphenyl-1,10-phenanthroline and 2,9-di(bi-phenyl-4-yl)-4,7-diphenyl-1,10-phenanthroline. Phenanthroline compounds that can be used as matrix materials are disclosed in EP 1786050 A1 and incorporated by reference.

The matrix compound of the first electron layer (**161**) and/or second electron transport layer (**162**) may be a compound that efficiently transports electrons, such as an anthracene-based compound, diphenylphosphine oxide based compound, or a phenanthroline based compound, preferably a matrix compound mentioned in Table 1. For

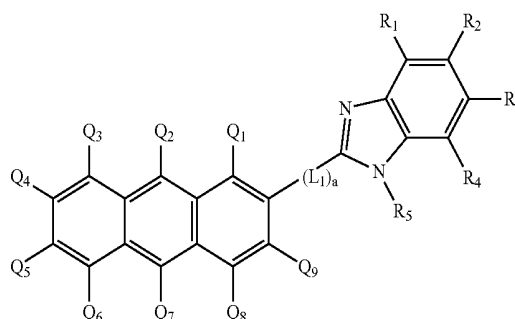
26

example, the matrix compound of the first electron layer (**161**) and/or second electron transport layer (**162**) may be selected from the group consisting of ADN and referred to as Formula 1, a compound represented by Formula 2, and a compound represented by Formula 3 below:

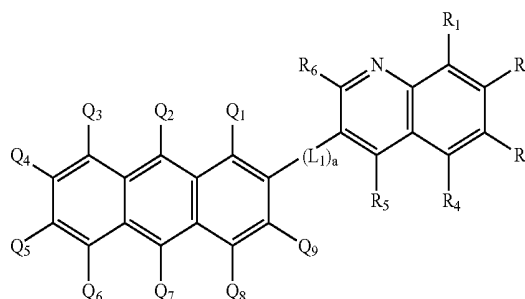
Formula 1 (ADN)



Formula 2



Formula 3



In Formulae 2 and 3, R_1 to R_6 are each independently a hydrogen atom, a halogen atom, a hydroxy group, a cyano group, a substituted or unsubstituted C_1 - C_{30} alkyl group, a substituted or unsubstituted C_1 - C_{30} alkoxy group, a substituted or unsubstituted C_1 - C_{30} acyl group, a substituted or unsubstituted C_2 - C_{30} alkenyl group, a substituted or unsubstituted C_2 - C_{30} alkynyl group, a substituted or unsubstituted C_6 - C_{30} aryl group, or a substituted or unsubstituted C_3 - C_{30} heteroaryl group. At least two adjacent R_1 to R_6 groups are optionally bonded to each other, to form a saturated or unsaturated ring. L_1 is a bond, a substituted or unsubstituted C_1 - C_{30} alkylene group, a substituted or unsubstituted C_6 - C_{30} arylene group, or a substituted or unsubstituted C_3 - C_{30} hetero arylene group. Q_1 through Q_9 are each independently a hydrogen atom, a substituted or unsubstituted C_6 - C_{30} aryl group, or a substituted or unsubstituted C_3 - C_{30} hetero aryl group, and "a" is an integer from 1 to 10.

For example, R_1 to R_6 may be each independently selected from the group consisting of a hydrogen atom, a

27

halogen atom, a hydroxy group, a cyano group, a methyl group, an ethyl group, a propyl group, a butyl group, a methoxy group, an ethoxy group, a propoxy group, a butoxy group, a phenyl group, a naphthyl group, an anthryl group, a pyridinyl group, and a pyrazinyl group.

In particular, in Formula 2 and/or 3, R_1 to R_4 may each be a hydrogen atom, R_5 may be selected from the group consisting of a halogen atom, a hydroxy group, a cyano group, a methyl group, an ethyl group, a propyl group, a butyl group, a methoxy group, an ethoxy group, a propoxy group, a butoxy group, a phenyl group, a naphthyl group, an anthryl group, a pyridinyl group, and a pyrazinyl group. In addition, in Formula 3, R_1 to R_6 may each be a hydrogen atom.

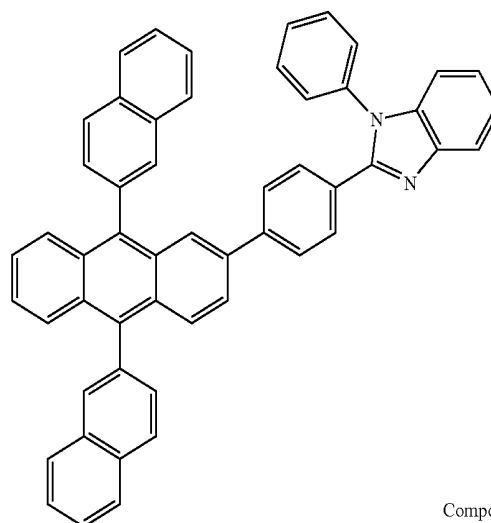
For example, in Formula 2 and/or 3, Q_1 to Q_9 are each independently a hydrogen atom, a phenyl group, a naphthyl group, an anthryl group, a pyridinyl group, and a pyrazinyl group. In particular, in Formulae 2 and/or 3, Q_1 , Q_3 - Q_6 , Q_8 and Q_9 are hydrogen atoms, and Q_2 and Q_7 may be each independently selected from the group consisting of a phenyl group, a naphthyl group, an anthryl group, a pyridinyl group, and a pyrazinyl group.

For example, L_1 , in Formula 2 and/or 3, may be selected from the group consisting of a phenylene group, a naphthylene group, an anthrylene group, a pyridinylene group, and a pyrazinylene group. In particular, L_1 may be a phenylene group or a pyridinylene group. For example, "a" may be 1, 2, or 3.

The matrix compound may be further selected from Compound 6 or 7 below:

28

Compound 6



Compound 7

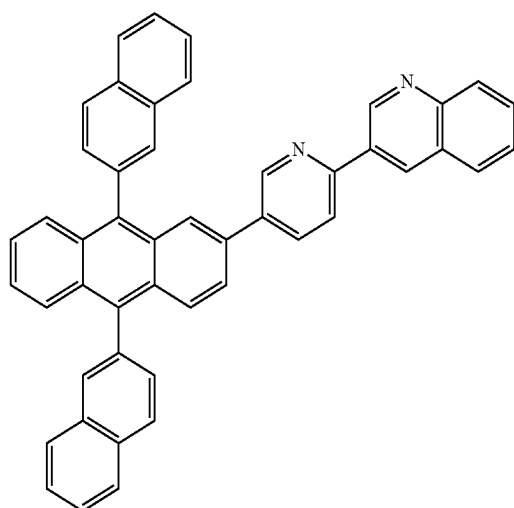


TABLE 1

Chemical structures of matrix materials that can be suitable used

Internal name	IUPAC name	Structure	Reference
MX 1	2-(4-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)-1-phenyl-1H-benzo[d]imidazole		US 6878469 B2

TABLE 1-continued

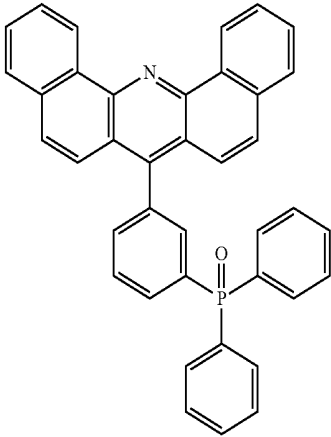
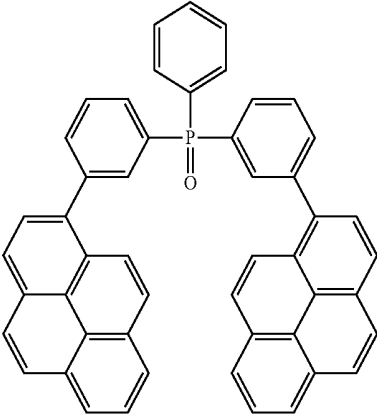
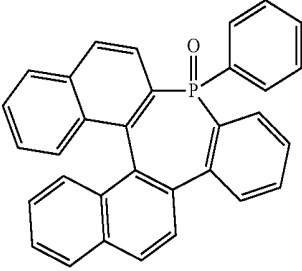
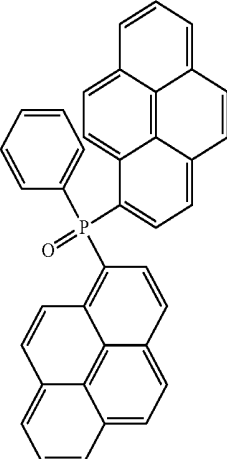
Chemical structures of matrix materials that can be suitable used			
Internal name	IUPAC name	Structure	Reference
MX 2	(3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide		EP 2395571B1, WO2013079217A1
MX 3	Phenylbis(3-(pyren-1-yl)phenyl)phosphine oxide		EP13187905.8
MX 4	3-Phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphepine-3-oxide		EP13199361.0
MX 5	Phenyl-di(pyren-1-yl)phosphine oxide		JP4876333

TABLE 1-continued

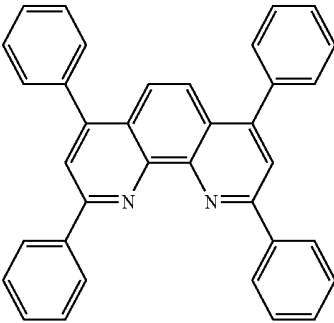
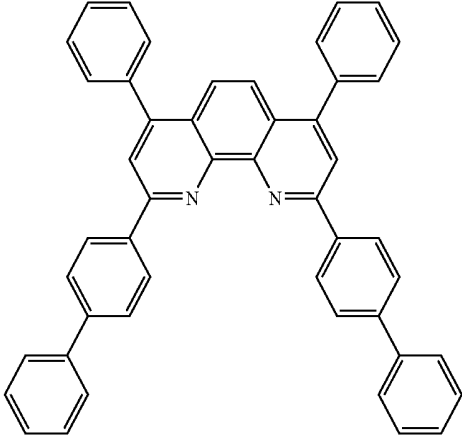
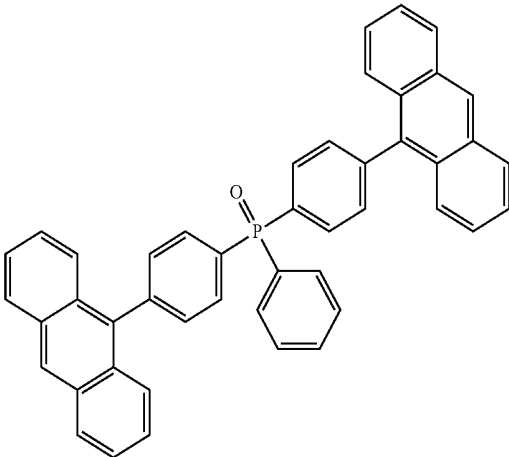
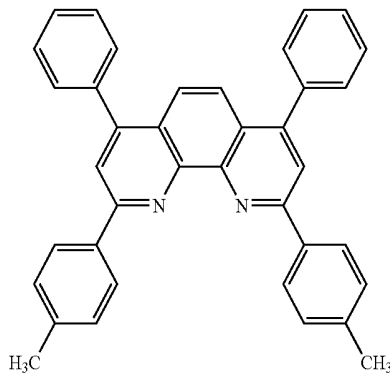
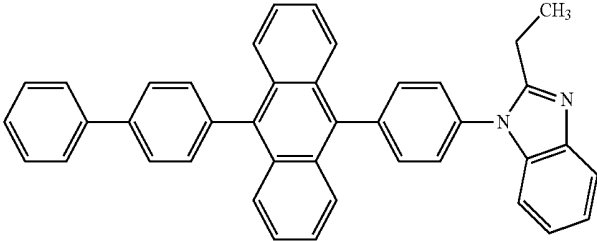
Chemical structures of matrix materials that can be suitable used			
Internal name	IUPAC name	Structure	Reference
MX 6	2,4,7,9-tetraphenyl-1,10-phenanthroline		EP1786050
MX 8	2,9-di(biphenyl-4-yl)-4,7-diphenyl-1,10-phenanthroline		EP1786050
MX 9	bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide		EP13187905
MX 10	4,7-diphenyl-2,9-di-p-tolyl-1,10-phenanthroline		EP1786050

TABLE 1-continued

Chemical structures of matrix materials that can be suitable used			
Internal name	IUPAC name	Structure	Reference
MX 11	1-(4-(10-([1,1'-biphenyl]-4-yl)anthracen-9-yl)phenyl)-2-ethyl-1H-benzo[d]imidazole		WO2010134352

Reduction and oxidation potentials are determined via cyclic voltammetry, using the Ferrocene/Ferrocenium (Fc/Fc⁺) redox couple as internal reference. A simple rule is very often used for the conversion of redox potentials into electron affinities and ionization potential: IP (in eV)=4.84 eV+e*E_{ox} (wherein E_{ox} is given in Volt vs. ferrocene/ferrocenium (Fc/Fc⁺) and EA (in eV)=4.84 eV+e*E_{red} (E_{red} is given in Volt vs. Fc/Fc⁺) respectively (see B. W. D'Andrade, Org. Electron. 6, 11-20 (2005)), e* is the elemental charge. It is common practice, even if not exactly correct, to use the terms "energy of the HOMO" E(HOMO) and "energy of the LUMO" E(LUMO), respectively, as synonyms for the ionization energy and electron affinity (Koopmans Theorem).

Table 2 below shows the energy levels of matrix compounds which may be suitably used according to the invention.

TABLE 2

Reduction and oxidation potential and energy of E(HOMO) and E(LUMO) of matrix materials				
Matrix compound	Oxidation potential vs Fc/Fc ⁺ /V	E(HOMO)/eV	Reduction potential vs Fc/Fc ⁺ /V	E(LUMO)/eV
MX1	>1.6	<-6.45	-2.32	-2.52
MX2	1.26	-6.1	-2.2	-2.64
MX4	>1.6	<-6.45	-2.62	-2.22
MX3	0.83	-5.67	-2.48	-2.36
MX9			-2.42	-2.42
MX10			-2.37	-2.47
MX11			-2.41	-2.38

The first electron transport layer **161** comprises a lithium halide or a lithium organic complex; and the second electron transport layer **162** comprises an elemental metal selected from the group of lithium, magnesium, and/or ytterbium.

According to another aspect the first electron transport layer **161** comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the second electron transport layer **162** comprises a lithium halide or a lithium organic complex.

According to another aspect the first electron transport layer **161** comprises a lithium halide or a lithium organic complex; and the second electron transport layer **162** comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the third electron transport layer **163** comprises a lithium halide or a lithium organic complex that is the same or differs from the lithium halide or lithium organic complex of the first electron transport layer **161**.

According to another aspect the first electron transport layer **161** comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; and the second electron transport layer **162** comprises a lithium halide or a lithium organic complex; and the third electron transport layer **163** comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium that is the same or differs from the elemental metal selected from the group of lithium, magnesium and/or ytterbium of the first electron transport layer **161**.

Suitable organic ligands to form a lithium organic complex that can be used for the first electron transport layer or the second electron transport layer are disclosed, and incorporated by reference, for example in WO 2013079676 A1, WO 2013079678 A1 and EP 2724388 and Kathirgamanathan, Poopathy; Arkley, Vincent; Surendrakumar, Sivagnanasundram; Chan, Yun F.; Ravichandran, Seenivasagam; Ganeshamurugan, Subramaniam; Kumaravel, Muttulingam; Antipan-Lara, Juan; Paramaswara, Gnanamolly; Reddy, Vanga R., Digest of Technical Papers—Society for Information Display International Symposium (2010), 41(Bk. 1), 465-468.

TABLE 3

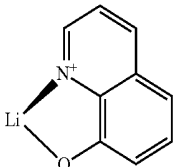
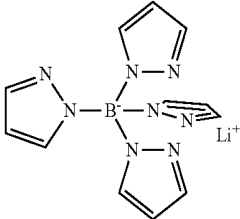
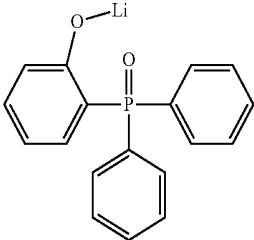
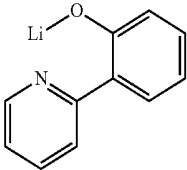
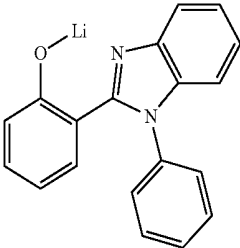
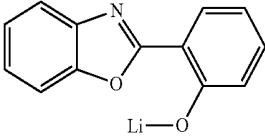
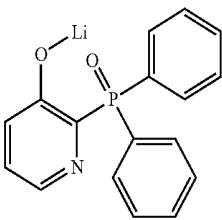
Lithium organic complex that can be suitable used		
IUPAC name	Structure	Reference
LiQ lithium 8-hydroxyquinolate		WO 2013079217 A1

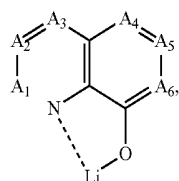
TABLE 3-continued

Lithium organic complex that can be suitable used		
IUPAC name	Structure	Reference
Li-1 lithium tetra(1H-pyrazol-1-yl)borate		WO 2013079676 A1
Li-2 lithium 2-(diphenylphosphoryl)phenolate		WO 2013079678A1
Li-3 lithium 2-(pyridin-2-yl)phenolate		JP2 008195623
Li-4 lithium 2-(1-phenyl-1H-benzod[imidazol-2-yl)phenolate		JP 2001291593
Li-5 lithium 2-(benzo[d]oxazol-2-yl)phenolate		US 20030165711
Li-6 lithium 2-(diphenylphosphoryl)pyridin-3-olate		EP 2724388

37

The organic ligand of the lithium organic complex of at least one electron transport layer may be selected from the group comprising a quinolate, a borate, a phenolate, a pyridinolate or a Schiff base ligand, or Table 3;

preferably the lithium quinolate complex has the formula I:



wherein

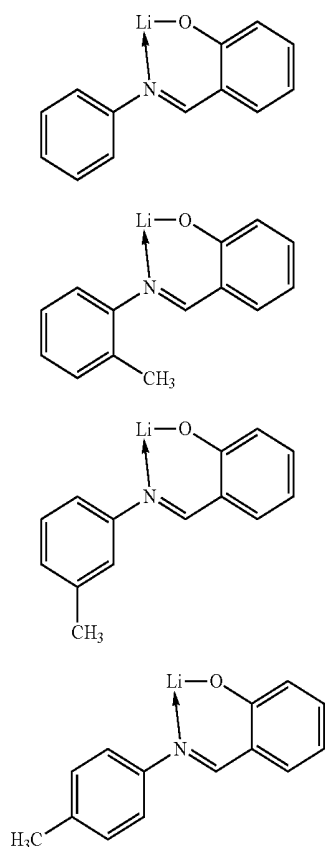
A1 to A6 are same or independently selected from CH, CR, N, O;

R is same or independently selected from hydrogen, halogen, alkyl or aryl or heteroaryl with 1 to 20 carbon atoms; and more preferred A1 to A6 are CH;

preferably the borate based organic ligand is a tetra(1H-pyrazol-1-yl)borate;

preferably the phenolate is a 2-(pyridin-2-yl)phenolate or a 2-(diphenylphosphoryl)phenolate;

preferably the lithium Schiff base has the structure 100, 101, 102 or 103:



more preferred the lithium organic complex is selected from a compound of Table 2.

The lithium halide of at least one electron transport layer may be selected from the group comprising a LiF, LiCl, LiBr or LiI, and preferably LiF.

38

The ETL layer stack thickness can be adjusted such that the light out coupling is maximized. Further ETL layer stack thickness can be adjusted for the desired color tuning, for example to achieve a deeper shade of blue, i.e. smaller CIEy.

The thicknesses of the first electron transport layer **161**, second electron transport layer **162** and/or third electron transport layer **163** may be the same or each independently in the range of about ≥ 0.5 nm to about ≤ 95 nm, preferably of about ≥ 3 nm to about ≤ 80 nm, further preferred of about ≥ 5 nm to about ≤ 60 nm, also preferred of about ≥ 6 nm to about ≤ 40 nm, in addition preferred about ≥ 8 nm to about ≤ 20 nm and more preferred of about ≥ 10 nm to about ≤ 18 nm.

When the thicknesses of the first electron transport layer **161**, second electron transport layer **162** and/or third electron transport layer **163** within this range, preferably of about ≥ 10 nm to about ≤ 18 nm, the electron transport layer stack **160** may effectively inject and transport electrons, without a substantial increase in driving voltage.

For blue emitting OLEDs, the thickness of the ETL layer stack is 10 to 50 nm, preferably 30 to 40 nm. For red and green emitting OLEDs, the thickness of ETLs is 20 to 100 nm, preferably 20-100 nm and more preferably 30-80 nm. The thickness is selected so as to maximize efficiency of light emission.

The amount of the lithium organic complex in at least one electron transport layer (**161**) may be in the range of about ≥ 10 mol-% to about ≤ 95 mol-%, preferably about ≥ 15 mol-% to about ≤ 90 mol-% and also preferred about ≥ 20 mol-% to about ≤ 80 mol-%, of the first electron transport layer **161**.

The amount of an elemental metal selected from the group of lithium, magnesium, and/or ytterbium in the second electron transport layer **162** may be in the range of about ≥ 1 wt.-% to about ≤ 60 wt.-%, preferably about ≥ 2 wt.-% to about ≤ 55 wt.-% and also preferred about ≥ 5 wt.-% to about ≤ 45 wt.-%, by weight of the second electron transport layer **162**.

The amount of the lithium halide or lithium organic complex in the first electron transport layer **161** may be in the range of about ≥ 10 mol-% to about ≤ 95 mol-%, preferably about ≥ 15 mol-% to about ≤ 90 mol-% and also preferred about ≥ 20 mol-% to about ≤ 80 mol-%, of the first electron transport layer **161**.

The amount of an elemental metal selected from the group of lithium, magnesium, and/or ytterbium in the second electron transport layer **162** may be in the range of about ≥ 10 mol-% to about ≤ 90 mol-%, preferably about ≥ 20 mol-% to about ≤ 85 mol-% and also preferred about ≥ 30 mol-% to about ≤ 80 mol-%.

However, the first electron transport layer **161** may comprises the elemental metal and the second electron transport layer **162** may comprises the lithium halide or lithium organic complex.

The ETL **160** may be formed on the EML **150** by vacuum deposition, spin coating, slot-die coating, printing, casting, or the like. When the ETL **160** is formed by vacuum deposition or spin coating, the deposition and coating conditions may be similar to those for formation of the HIL **130**. However, the deposition and coating conditions may vary, according to a compound that is used to form the ETL **160**.

Using vacuum deposition, the first electron transport layer **161** of the ETL **160** may be formed using a first deposition source to deposit a matrix compound, and a second deposition source to deposit a lithium halide or lithium organic complex. The first deposition source and the second deposition source are positioned relative to one another, such that

a mixed deposition region of the first electron transport layer **161** is formed directly on the EML **150**.

The second electron transport layer **162** of the ETL **160** may be formed using a first or a third deposition source, for example if the matrix material is different to the ETL **161**, and a third or fourth deposition source is used to deposit the elemental metal selected from the group of lithium, magnesium and/or ytterbium.

The deposition sources are positioned relative to one another, such that a mixed deposition region of the second electron transport layer **162** is formed directly on the first electron transport layer **161**.

The stacking process is more simply and quickly performed, as compared to prior methods. In particular, since a plurality of ETL layers may be almost simultaneously deposited in a single chamber, the chamber may not be required to be exhausted after the formation of each layer.

The EIL **180**, which facilitates injection of electrons from the cathode, may be formed on the ETL **160**, preferably directly on the second electron transport layer **162**. Examples of materials for forming the EIL **180** include LiF, NaCl, CsF, Li₂O, BaO, Ca, Ba, Yb, Mg which are known in the art. Deposition and coating conditions for forming the EIL **180** are similar to those for formation of the HIL **130**, although the deposition and coating conditions may vary, according to a material that is used to form the EIL **180**.

The thickness of the EIL **180** may be in the range of about 0.1 nm to 10 nm, for example, in the range of 0.5 nm to 9 nm. When the thickness of the EIL **180** is within this range, the EIL **180** may have satisfactory electron-injecting properties, without a substantial increase in driving voltage.

The second cathode electrode **190** is formed on the EIL **180** if present. The second cathode electrode **190** may be a cathode, which is an electron-injecting electrode. The second electrode **190** may be formed of a metal, an alloy, an electrically conductive compound, or a mixture thereof. The second electrode **190** may have a low work function. For example, the second electrode **190** may be formed of lithium (Li), magnesium (Mg), aluminum (Al), aluminum (Al)-lithium (Li), calcium (Ca), barium (Ba), ytterbium (Yb), magnesium (Mg)-indium (In), magnesium (Mg)-silver (Ag), or the like. In addition, the second electrode **190** may be formed of a transparent conductive material, such as ITO or IZO.

The thickness of the cathode electrode **190** may be in the range of about 5 nm to 1000 nm, for example, in the range of 10 nm to 100 nm. When the cathode electrode **190** is in the range of 5 nm to 50 nm, the electrode will transparent even if a metal or metal alloy is used.

Since the layers of the ETL **160** have similar or identical energy levels, the injection and transport of the electrons may be controlled, and the holes may be efficiently blocked. Thus, the OLED **100** may have long lifetime.

FIGS. **5** and **6** is a schematic sectional view of an OLED **200**, according to another exemplary embodiment of the present invention. FIGS. **3** and **4** differ from FIGS. **5** and **6** in that the OLED **200** has no electron injection layer (EIL) **180**.

Referring to FIGS. **5** and **6** the OLED **200** includes a substrate **110**, a first electrode **120**, a HIL **130**, a HTL **140**, an EML **150**, an ETL **160**, and a second electrode **190**. The ETL stack **160** of FIG. **5** includes a first ETL layer **161** and a second ETL layer **162** and the ETL stack **160** of FIG. **6** includes a first ETL layer **161**, a second ETL layer **162** and a third ETL layer **163**.

The electron transport layer stack **160** of FIG. **5** comprises of at least two electron transport layers **161** and **162**, wherein

a first electron transport layer **161** and a second electron transport layer **162** comprises at least one matrix compound and in addition,

the first electron transport layer comprises a lithium halide or a lithium organic complex, and

the second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; wherein the first electron transport layer is arranged closest to an anode and the second electron transport layer is arranged closest to a cathode.

The electron transport layer stack **160** of FIG. **6** comprises of at least three electron transport layers **161**, **162** and **163**, wherein a first electron transport layer **161**, a second electron transport layer **162** and a third electron transport layer **163** comprises at least one matrix compound and in addition,

the first electron transport layer **161** and third electron transport layer **163** comprises a lithium halide or a lithium organic complex, and

the second electron transport layer **162** comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium; wherein the first electron transport layer **161** is arranged closest to an anode and the third electron transport layer **163** is arranged closest to a cathode.

The layers of the ETL **161** and **162** or of the ETL **161**, **162** and **163** have similar or identical energy level. Further, the OLED **200** have an improved lifetime (LT). The substrate **110**, the first electrode **120**, the hole injection layer **130**, the hole transport layer **140**, the emission layer **150**, and the electron transport layer **161** and **162** of the OLED **200** of FIG. **5** or the electron transport layer **161**, **162** and **163** of the OLED **200** of FIG. **6** are similar to corresponding elements described with reference to FIGS. **3** and **4**, respectively. Even though the structure of the OLED **200** and the method of manufacturing the OLED **200** are described with reference to FIGS. **3** and **4**, other methods known in the art can be used. For example, the ETL stack **160** may include three or more ETL layers but two ETL layers of ETL **161** and **162** may be preferred.

In the description above the method of manufacture an OLED of the present invention is started with a substrate **110** onto which a first anode electrode **120** is formed, on the first anode electrode **120** an emission layer **150** is formed. An electron transport layer stack **160** is formed on the emission layer **150**, wherein the first electron transport layer **161** is formed on the emission layer **150** and the second electron transport layer **162** is formed directly on the first electron transport layer **161**, on the electron transport layer stack **160**, in this case on the second electron transport layer **162**, a cathode electrode **190** is formed, optional a hole injection layer **130**, and a hole transport layer **140**, are formed in that order between the first anode electrode **120** and the electron transport layer stack **160**, an optional hole blocking layer is arranged between the emission layer and the ETL layer stack, and optionally an electron injection layer **180** is arranged between the electron transport layer **160** and the second cathode electrode **190**.

However, the OLED of the present invention can be manufactured also the other way around, starting with the second cathode electrode **190** onto which optionally an electron injection layer **180** is formed. On the second cathode electrode **190** or on the electron injection layer **180**, if present, the second electron transport layer **162** is formed and directly on the second electron transport layer **162** the first electron transport layer **161** is formed and so on.

In case of a three layer electron transport layer stack **160**, the second electron layer **162** is formed on the first electron layer **161** and the third electron layer **163** is formed on the second electron layer **162**. Then a cathode electrode **190** is formed, optional a hole injection layer **130**, and a hole transport layer **140**, are formed in that order between the first anode electrode **120** and the electron transport layer stack **160**, an optional hole blocking layer is arranged between the emission layer and the ETL layer stack, and optionally an electron injection layer **180** is arranged between the electron transport layer **160** and the second cathode electrode **190**.

According to another embodiment the electron transport layer stack **160** may form part of a charge generation layer (CGL).

The term "charge generation layer" also named "CGL" stands for a layer structure of a second electron transport layer adjacent arranged to a hole injection layer, or a layer structure of a second electron transport layer adjacent arranged to an interlayer that is adjacent arranged to a hole injection layer.

According to one embodiment of an OLED comprising a charge generation layer, the first electron transport layer comprised a Li organic complex and/or Li halide, and the second electron transport layer, which is part of the charge generation layer, comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium.

The optional interlayer comprises CN-HAT (CAS 105598-27-4) or CuPc. The interlayer can be used to increase lifetime of the OLED-device. Suitable interlayer compounds are disclosed in WO 2010/132236 A1 and are fully incorporated by reference.

According to one aspect an OLED can comprise a layer structure of a substrate that is adjacent arranged to an anode electrode, the anode electrode is adjacent arranged to a first hole injection layer, the first hole injection layer is adjacent arranged to a first hole transport layer, the first hole transport layer is adjacent arranged to a first emission layer, the first emission layer is adjacent arranged to a first electron transport layer, the first electron transport layer is adjacent arranged to a second electron transport layer, the second electron transport layer is adjacent arranged to an interlayer, the interlayer is adjacent arranged to a second hole injection layer, the second hole injection layer is adjacent arranged to a second hole transport layer, the second hole transport layer is adjacent arranged to a second emission layer, between the second emission layer and the cathode electrode an optional electron transport layers and/or an optional injection layer are arranged.

According to another aspect an OLED can comprise a layer structure of a substrate that is adjacent arranged to an anode electrode, the anode electrode is adjacent arranged to a first hole injection layer, the first hole injection layer is adjacent arranged to a first hole transport layer, the first hole transport layer is adjacent arranged to a first emission layer, the first emission layer is adjacent arranged to a first electron transport layer, the first electron transport layer is adjacent arranged to a second electron transport layer, the second electron transport layer is adjacent arranged to a second hole injection layer, the second hole injection layer is adjacent arranged to a second hole transport layer, the second hole transport layer is adjacent arranged to a second emission layer, between the second emission layer and the cathode electrode an optional electron transport layers and/or an optional injection layer are arranged.

According to another aspect the OLED may comprise the following layers arranged in the order:

substrate/anode electrode/first hole injection layer/first hole transport layer/first emission layer/first ETL/second ETL/optional interlayer/second hole injection layer/second hole transport layer/second emission layer/optional electron transport layers/optional injection layers/cathode electrode.

According to another aspect the OLED may comprise the following layers arranged in the order of a substrate, an anode electrode, a first hole injection layer, a first hole transport layer, a first emission layer, a first electron transport layer, a second electron transport layer, an optional interlayer, a second hole injection layer, a second hole transport layer, optional a triplet control layer a second emission layer, an optional electron transport layer, optional a third electron transport layer, an optional injection layer, and a cathode electrode.

The function of the triplet control layer is to reduce quenching of triplets if a phosphorescent green or blue emission layer is used. Thereby, higher efficiency of light emission from a phosphorescent emission layer can be achieved. The triplet control layer is selected from triarylamine compounds with a triplet level above the triplet level of the phosphorescent emitter in the adjacent emission layer. Suitable triplet control layer, in particular the triarylamine compounds, are described in EP 2 722 908 A1, and fully incorporated here by reference.

FIG. 7 shows a tandem OLED **300** that comprises a layer structure in the following order:

Substrate **110**/anode electrode **120**/first hole injection layer **130**/first hole transport layer **140**/first emission layer fluorescent blue emitting layer **150**/first electron transport layer **161**/second electron transport layer **162**/second hole injection layer **131**/second hole transport layer **141**/triplet control layer **170**/second emission layer phosphorescent green emitting layer **151**/third electron transport layer **163**/electron injection layer **180**/ and a cathode electrode **190**.

According to another aspect the OLED may comprise the following layers arranged in the order of a substrate, an anode electrode, a first hole injection layer, a first hole transport layer, optional a first triplet control layer, a first emission layer, a first electron transport layer, a second electron transport layer, an optional interlayer, a second hole injection layer, a second hole transport layer, optional a second triplet control layer, a second emission layer, an optional electron transport layer, optional a third electron transport layer, an optional injection layer, and a cathode electrode.

An OLED comprising two or more emission layers and one or more charge generation layers may be described as tandem OLED or stacked OLED.

While not shown in FIGS. 3 to 7, a sealing layer may further be formed on the second electrodes **190**, in order to seal the OLEDs **100**, **200**, **300**. In addition, various other modifications may be applied thereto.

Hereinafter, one or more exemplary aspects will be described in detail with, reference to the following examples. However, these examples are not intended to limit the purpose and scope of the one or more exemplary aspects.

EXAMPLES

General Procedure for OLEDs with One Emission Layer (Single OLED)

For bottom emission devices, a 15 Ω/cm^2 glass substrate (available from Corning Co.) with 100 nm ITO was cut to a size of 50 mm×50 mm×0.7 mm, ultrasonically cleaned with

isopropyl alcohol for 5 minutes and then with pure water for 5 minutes, and cleaned again with UV ozone for 30 minutes, to prepare a first electrode.

For top emission devices, the anode electrode was formed from 100 nm silver on glass which was prepared by the same methods as described above.

Then, 80 wt.-% of N4,N4"-di(naphthalen-1-yl)-N4,N4"-diphenyl-[1,1':4',1"-terphenyl]-4,4"-diamine and 20 wt.-% of 2,2',2"-(cyclopropane-1,2,3-triylidene)tris(2-(p-cyanotetrafluorophenyl)acetonitrile) was vacuum deposited on the ITO electrode, to form a HIL having a thickness of 10 nm. Then N4,N4"-di(naphthalen-1-yl)-N4,N4"-diphenyl-[1,1':4',1"-terphenyl]-4,4"-diamine was vacuum deposited on the HIL, to form a HTL having a thickness of 130 nm. 97 wt.-% of ABH113 (Sun Fine Chemicals) as a host and 3 wt.-% of NUBD370 (Sun Fine Chemicals) as a dopant were deposited on the HTL, to form a blue-emitting EML with a thickness of 20 nm.

Then the ETL-layer stack is formed by depositing the first electron transport layer (ETL 1) including a matrix compound according to Example 1 to Example 21 and comparative examples 2 to 5 by depositing the matrix compound from a first deposition source and the lithium organic complex or lithium halide of from a second deposition source directly on the EML.

Then the second electron transport layer (ETL 2) including a matrix compound according to Example 1 to Example 28 and comparative examples 1 to 9 is formed by depositing the matrix compound from a first deposition source, if the same matrix compound is used as in the first electron transport layer, or a third deposition source, if the matrix compound is different from the matrix compound used in the first electron transport layer.

A lithium organic complex or lithium halide is deposited from a third deposition source directly on the first electron transport layer (ETL 1) and an elemental metal selected from the group of lithium, magnesium and/or ytterbium is deposited from a fourth deposition source directly on the second electron transport layer (ETL 2).

For an electron transport layer with three electron transport layers (ETL 1, ETL 2 and ETL 3) the corresponding electron transport layer is formed as described above.

For the comparative examples land 2 only one electron transport layer ETL 2 is formed and for the other comparative examples two electron transport layers of ETL 1 and ETL 2 are formed.

The wt.-% of the lithium organic complex for the ETL1 as well as for the ETL 2 can be taken from Tables 4 to 10, whereby the wt.-% amount of the matrix compound is added to 100 wt.-% respectively. That means, that the matrix compound of ETL 1 are added in a wt.-% amount such that the given wt.-% of the lithium organic complex for the ETL1 and the matrix compound of the ETL 1 are in total 100 wt.-%, based on the weight of the ETL 1; and, the matrix compound of ETL 2 are added in a wt.-% amount such that the given wt.-% of the elemental metal selected from the group of lithium, magnesium and/or ytterbium for the ETL2 and the matrix compound of the ETL 2 are in total 100 wt.-%, based on the weight of the ETL 2. Further, the

thickness d (in nm) of the ETL 1 and ETL 2 can be taken from Tables 4 to 10. The cathode was evaporated at ultra-high vacuum of 10^{-7} bar. Therefore, a thermal single co-evaporation of one or several metals was performed with a rate of 0, 1 to 10 nm/s (0.01 to 1 Å/s) in order to generate a homogeneous cathode with a thickness of 5 to 1000 nm. For top emission devices, the cathode electrode was formed from 13 nm magnesium (90 vol.-%)-silver (10 vol.-%) alloy, followed by 60 nm N4,N4"-di(naphthalen-1-yl)-N4,N4"-diphenyl-[1,1':4',1"-terphenyl]-4,4"-diamine. For bottom emission devices, the cathode electrode was formed from 100 nm aluminum.

The OLED stack is protected from ambient conditions by encapsulation of the device with a glass slide. Thereby, a cavity is formed, which includes a getter material for further protection.

To assess the performance of the inventive examples compared to the prior art, the current efficiency is measured under ambient conditions (20° C.). Current voltage measurements are performed using a Keithley 2400 sourcemeter, and recorded in V. At 15 mA/cm², a calibrated spectrometer CAS140 from Instrument Systems is used for measurement of CIE coordinates and brightness in Candela. Lifetime LT of the device is measured at ambient conditions (20° C.) and 15 mA/cm², using a Keithley 2400 sourcemeter, and recorded in hours. The brightness of the device is measured using a calibrated photo diode. The lifetime LT is defined as the time till the brightness of the device is reduced to 97% of its initial value.

In bottom emission devices, the emission is predominately Lambertian and quantified in percent external quantum efficiency (EQE). To determine the EQE in % the light output of the device is measured using a calibrated photo-diode at 10 mA/cm².

In top emission devices, the emission is forward directed, non-Lambertian and also highly dependent on the micro-cavity. In order to minimize the effect of the micro-cavity and thus of the emission color on the device performance, the efficiency Eff. is measured in Candela per Ampere (cd/A) and divided by the CIE-y.

In tandem OLED devices, two or more emission layers are present and there is a higher probability of holes and electrons recombining to form excitons. Therefore, the efficiency EQE of tandem OLEDs is significantly higher than of single OLEDs comprising just one emission layer.

Technical Effect of the Invention

Bottom Emission Single OLED Devices

a) Lifetime and Efficiency Improvement with Two Electron Transport Layers (ETL1 and ETL 2)

In Table 4 results are shown for top emission devices with two different matrix compounds in the ETL-stack of first electron transport layer (ETL1) and second electron transport layer (ETL 2). An external quantum efficiency (EQE) and lifetime improvement is observed compared to the emission device with one electron transport layer only—Table 4.

TABLE 4

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with two ETLs										
ETL1	wt.-% Li organic complex* ¹	d (ETL1)/ nm	ETL2	wt.-% Li organic complex* ¹	wt.-% Metal dopant* ²	d (ETL2)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h	
Comp. example 1	none		MX2:Mg		5	36	3.70	4.20	10	
Comp. example 2	none		MX2:LiQ:Mg	47.5	5	36	3.79	5.83	12	
Example 1	MX2:LiQ	50	26	MX2:Mg		5	11	4.33	6.25	130

*¹= the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*²= the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

In the Table 4 above a device data for a single ETL device compared to a device containing two electron transport layers is shown. As can be seen, the lifetime and efficiency are improved for devices with two electron transport layers according to the invention compared to devices with just one electron transport layer (Comparative example 1).

The lifetime and efficiency are also improved when comparing a single ETL device comprising lithium organic complex and magnesium in the one electron transport layer compared to a device with two electron transport layers where the lithium organic complex is present in the first electron transport layer and magnesium in the second electron transport layer (Comparative example 2).

TABLE 5

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with two ETLs									
		wt.-% Li organic complex* ¹	d (ETL1)/ nm		wt.-% Metal dopant* ²	d (ETL2)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
ETL1				ETL2					
Comparative example 3	MX1:LiQ	50	19	MX1:Ca	5	17	3.77	5.48	55
Example 2	MX1:LiQ	50	10	MX1:Mg	5	26	7.20	4.72	130
Example 3	MX2:LiQ	50	26	MX2:Mg	5	11	4.33	6.25	130
Example 4	MX2:LiQ	50	26	MX2:Yb	5	10	4.52	5.79	170
Example 5	MX2:LiQ	50	20	MX2:Li	5	16	4.37	6.15	150

*¹= the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*²= the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

In the Table 5 above results for external quantum efficiency and lifetime are shown for devices containing benzimidazole matrix compound MX 1 in the first and second electron transport layer. In comparison to comparative example 3, a significant improvement in lifetime is observed when calcium is replaced by magnesium in the second electron transport layer (Example 2). When benzimidazole

matrix compound MX 1 is replaced by phosphine oxide matrix compound MX 2 very good lifetime is maintained, and the external quantum efficiency is improved (Example 3 compared to Example 2). Additionally, the voltage is much reduced in Example 3 compared to Example 2. A further increase in lifetime is achieved when magnesium is replaced with lithium and ytterbium (Examples 4 and 5).

TABLE 6

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with two ETLs									
		wt.-% Li organic complex* ¹	d (ETL1)/ nm		wt.-% Metal dopant* ²	d (ETL2)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
	ETL1			ETL2					
Example 6	MX2:LiQ	50	26	MX2:Mg	5	11	4.33	6.25	130
Example 7	MX2:LiQ	50	26	MX2:Yb	5	10	4.52	5.79	170
Example 8	MX4:Li-2	60	26	MX4:Mg	5	10	4.52	6.59	150
Example 9	MX9:Li-2	50	21	MX9:Mg	5	15	4.21	5.50	140

TABLE 6-continued

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with two ETLs									
	ETL1	wt.-% Li organic complex* ¹	d (ETL1)/ nm	ETL2	wt.-% Metal dopant* ²	d (ETL2)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
Example 10	MX9:Li-2	50	26	MX9:Yb	5	10	4.69	5.42	300
Example 11	MX9:Li-2	50	16	MX9:Yb	5	20	4.47	5.39	220

*¹= the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*²= the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

In the Table 6 above a comparison is shown of various phosphine oxide matrix compounds and lithium organic complex Li-2. The lifetime is improved for both magnesium and ytterbium compared to comparative examples 1, 2 and 3. As can be seen in Example 10, a lifetime improvement is observed even for a thicker first electron transport layer and a thinner second electron transport layer. As can be seen in Example 11, a lifetime improvement is observed even for a thinner first electron transport layer and a thicker second electron transport layer. The best lifetime in Table 6 is achieved for 26 nm first ETL and 10 nm second ETL, see Example 10. Depending on the matrix compound, an increase in efficiency can also be observed, for example matrix compound MX4 of Example 8 gives higher external quantum efficiency (EQE) than MX2 or MX9.

In summary, improved lifetime is observed for magnesium, ytterbium and lithium in the second electron transport layer compared to the devices of comparative examples where calcium has been used. For certain combinations of matrix compounds and lithium organic complex, an increase in efficiency has been achieved according to the invention, for example MX2, doped with LiQ, and MX4, doped with Li-2.

In Table 7 below a bottom-emission device with the same matrix material in the first and second electron transport layer is compared with a device of a first matrix compound in the first electron transport layer and a different second matrix compound in the second electron transport layer.

TABLE 7

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with two ETLs									
	ETL1	wt.-% Li organic complex* ¹	d (ETL1)/ nm	ETL2	wt.-% Metal dopant* ²	d (ETL2)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
Example 12	MX2:LiQ	50	26	MX2:Mg	5	11	4.33	6.25	130
Example 13	MX3:LiQ	60	20	MX2:Mg	5	16	4.92	5.27	200

*¹= the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*²= the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

In the Table 7 above results for devices wherein the HOMO level of the first matrix compound is about 0.43 eV shallower (shallower means closer to vacuum level) compared to the second matrix compound of Example 13. Additionally, the LUMO level of the first matrix compound is about 0.28 eV shallower (closer to vacuum level) than the LUMO of the second matrix compound. The lifetime is increased compared to devices with the same matrix compound in both ETL layers.

In Table 8 below a comparison of two matrix materials is shown, wherein the first matrix material has a deeper HOMO level than the second matrix material.

TABLE 8

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with two ETLs									
	ETL1	wt.-% Li organic complex* ¹	d (ETL1)/ nm	ETL2	wt.-% Metal dopant* ²	d (ETL2)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
Example 14	MX4:Li-2	60	20	MX4:Mg	5	16	4.40	6.57	130
Example 15	MX4:Li-2	60	20	MX2:Mg	5	16	4.52	6.36	145

*¹= the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*²= the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

In the Table 8 above results for bottom emission devices wherein the HOMO level of the first matrix compound of Example 14 is about >0.35 eV deeper (deeper means further away from vacuum level) compared to the second matrix compound of Example 15 is shown. The LUMO level of the first matrix compound is about 0.42 eV shallower compared to the LUMO level of the second matrix compound. Again, the lifetime is improved over the device with the same matrix compound in both ETL layers. In summary, a significant lifetime improvement is achieved irrespective of the off-set in HOMO level between the first and second matrix compound.

In Table 9 below bottom emission devices are compared with various cathode materials of aluminum and silver with a thickness of 100 nm.

TABLE 9

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with two ETLs										
	ETL1	wt.-% Lithium organic complex *1	d (ETL1)/ nm	ETL2	wt.-% Metal dopant *2	d (ETL2)/ nm	Cathode	V at 10 mA/cm ² /V	EQE/ %	LT/ h
Comp. example 4	MX1:LiQ	50	19	MX1:Ca	5	17	Al	3.77	5.48	55
Comp. example 5	MX1:LiQ	50	19	MX1:Ca	5	16	Ag	3.66	4.89	47
Example 16	MX2:LiQ	50	26	MX2:Mg	5	11	Al	4.33	6.25	130
Example 17	MX2:LiQ	50	20	MX2:Mg	5	16	Ag	4.06	5.25	100

*1 = the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*2 = the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

In Table 9 above bottom-emission devices are shown with Al and Ag cathode.

As can be seen for Comparative Examples 4 and 5, the lifetime with Ag cathode is slightly shorter compared to the Al cathode. When phosphine oxide host matrix MX2 is used in both layers and ETL 2 contains Mg, the lifetime with both Al and Ag cathode is significantly improved over the Comparative Examples 4 and 5.

Lifetime and efficiency improvement with three electron transport layers (ETL1, ETL 2, and ETL 3).

In Table 10 below are shown voltages for OLEDs with different thicknesses of ETL2, while keeping the thickness of ETL1 constant.

TABLE 10

Voltage at 10 mA/cm ² of bottom emission OLEDs with different thicknesses of ETL1 and ETL2							
	ETL1	wt.-% Lithium organic complex*1	d (ETL1)/ nm	ETL2	wt.-% Metal dopant*2	d (ETL2)/ nm	V at 10 mA/cm ² /V
Example 18	MX2:LiQ	50	20	MX2:Mg	5	16	4.09
Example 19	MX2:LiQ	50	20	MX2:Mg	5	56	4.09
Example 20	MX2:LiQ	50	20	MX2:Mg	5	96	4.1
Example 21	MX2:LiQ	50	20	MX2:Mg	5	136	4.09

*1 = the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*2 = the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

As can be seen in Table 10 above, the voltage does not change with the thickness of the electron transport layer containing elemental metal (ETL2). Even when the thick-

ness of ETL2 is increased from 16 to 136 nm, the voltage does not increase (Examples 18 and 21). In manufacturing, this is a very important feature as it allows fine-tuning of the micro-cavity through optimisation of the layer thickness without loss in conductivity. The micro-cavity influences the emission spectrum and efficiency of an OLED. In devices with an electron transport layer containing elemental metal, the thickness of this layer can be adjusted to optimize the emission spectrum and efficiency without increase in voltage.

In Table 11 below a comparison of two matrix materials is shown, wherein the first matrix material is selected from

a anthracene or phenanthroline compound and the second matrix compound is selected from a phosphine oxide compound.

TABLE 11

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with two ETLs									
	ETL1	wt.-% Li organic complex* ¹	d (ETL1)/ nm	ETL2	wt.-% Metal dopant* ²	d (ETL2)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
Comparative example 6	MX1:LiQ	50	19	MX1:Ca	5	17	3.77	5.48	55
Example 22	MX10:LiQ	50.5	11	MX2:Mg	5.4	26	3.4	7.6	20
Example 23	MX11:LiQ	50	17	MX2:Mg	5.3	20	4.3	6.5	35

*¹= the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*²= the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

As can be seen in Table 11 above, the efficiency EQE for examples 22 and 23 are improved significantly compared to comparative example 6. In particular example 22, for first matrix compound selected from phenanthroline MX10 and second matrix compound selected from phosphine oxide MX2, very high efficiency EQE is obtained.

Bottom Emission Single OLED Devices

b) Lifetime and efficiency improvement with three electron transport layers (ETL 1, ETL 2 and ETL 3)

a) A device is fabricated with three ETL layers. ETL 1 (closest to the emission layer) contains a matrix compound and a lithium halide or lithium organic complex. ETL 2 (adjacent to ETL 1) contains a matrix compound and elemental metal, for example Mg or Yb. ETL 3 (adjacent to ETL 2 and closest to the cathode) contains a matrix compound and the same lithium halide or lithium organic complex as used in ETL 1. An Al or Ag cathode is deposited on top. Preferably the same phosphine oxide based matrix compound is used in the three electron transport layers. The external quantum efficiency EQE is >5.5% and the LT is >70 h, see Table 12.

b) A device is fabricated with three ETL layers. ETL 1 (closest to the emission layer) contains a matrix compound

and an elemental metal, for example Mg or Yb. ETL 2 (adjacent to ETL 1) contains a matrix compound and a lithium halide or lithium organic complex. ETL 3 (adjacent to ETL 2 and closest to the cathode) contains a matrix compound and the same elemental metal as used in ETL 1. An Al or Ag cathode is deposited on top. Preferably the same phosphine oxide based matrix compound is used in the three electron transport layers. The external quantum efficiency EQE is >5.5% and the LT is >70 h.

Top Emission Devices

Lifetime and Efficiency Improvement with Three Electron Transport Layers (ETL 1, ETL 2 and ETL 3)

A device is fabricated with three ETL layers. ETL 1 (closest to the emission layer) contains a matrix compound and a lithium halide or lithium organic complex. ETL 2 (adjacent to ETL 1) contains a matrix compound and magnesium. ETL 3 (adjacent to ETL 2 and closest to the cathode) contains a matrix compound and the same lithium halide or lithium organic complex as used in ETL 1. An Ag:Mg (10:90 vol.-%) cathode is deposited on top. Preferably the same phosphine oxide based matrix compound is used in the three electron transport layers. The external quantum efficiency EQE and lifetime LT are significantly improved over the comparative example 8, see Table 13.

TABLE 12

External quantum efficiency (EQE) and lifetime of bottom emission OLEDs with three ETLs and Al cathode												
	ETL1	wt.-% Lithium organic complex * ¹	d (ETL1)/ nm	ETL2	wt.-% Metal dopant * ²	d (ETL2)/ nm	ETL3	wt.-% Lithium organic complex * ³	d (ETL3)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
Comp. example 7	MX1:LiQ	50	19	MX1:Ca	5	17	—	—	—	3.8	5.5	55
Example 24	MX2:LiQ	50	11	MX2:Mg	5.2	17	MX2:LiQ	50	11	3.9	6.5	70

*¹ = the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*² = the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

*³ = the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL3

TABLE 13

External quantum efficiency (EQE) and lifetime of top emission OLEDs with three ETLs												
	ETL1	wt.-% Lithium organic complex * ¹	d (ETL1)/ nm	ETL2	wt.-% Metal dopant * ²	d (ETL2)/ nm	ETL3	wt.-% Lithium organic complex * ³	d (ETL3)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
Comp. example 8	—	—	—	MX2:Mg	5.1	36	—	—	—	3.8	6.9	53
Example 25	MX2:LiQ	49.5	10	MX2:Mg	5	16	MX2:LiQ	49.5	11	3.6	10.2	70

*¹ = the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*² = the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

*³ = the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL3

Bottom Emission Tandem OLED Devices
General Procedure for OLEDs with Two Emission Layers
(Tandem OLED)

For bottom emission devices, a 15 Ω/cm^2 glass substrate (available from Corning Co.) with 100 nm ITO was cut to a size of 50 mm $\times$ 50 mm $\times$ 0.7 mm, ultrasonically cleaned with isopropyl alcohol for 5 minutes and then with pure water for 5 minutes, and cleaned again with UV ozone for 30 minutes, to prepare a first electrode.

For top emission devices, the anode electrode was formed from 100 nm silver on glass which was prepared by the same methods as described above.

Then, 92 wt.-% of Biphenyl-4-yl(9,9-diphenyl-9H-fluoren-2-yl)-[4-(9-phenyl-9H-carbazol-3-yl)phenyl]-amine (CAS 1242056-42-3) and 8 wt.-% of 2,2',2''-(cyclopropane-1,2,3-triylidene)tris(2-(p-cyanotetrafluorophenyl)acetonitrile) was vacuum deposited on the ITO electrode, to form a HIL having a thickness of 10 nm. Then Biphenyl-4-yl(9,9-diphenyl-9H-fluoren-2-yl)-[4-(9-phenyl-9H-carbazol-3-yl)phenyl]-amine was vacuum deposited on the HIL, to form a HTL having a thickness of 135 nm. 97 wt.-% of ABH113 (Sun Fine Chemicals) as a host and 3 wt.-% of NUBD370 (Sun Fine Chemicals) as a dopant were deposited on the HTL, to form a blue-emitting EML with a thickness of 25 nm.

Then the ETL-layer stack is formed by depositing the first electron transport layer (ETL 1) including a matrix compound according to Example 26 to Example 28 by depositing the matrix compound from a first deposition source and the lithium organic complex or lithium halide of from a second deposition source directly on the EML.

Then the second electron transport layer (ETL 2) including a matrix compound according to Example 26 to Example 28 and comparative example 9 is formed by depositing the

a thickness of 15 nm. 90 wt.-% EL-GHB914S (Samsung SDI) as a host and 10 wt.-% EL-GD0108S (Samsung SDI) as phosphorescent green emitter are vacuum deposited on the triplet control layer, to form a green emitting EML having a thickness of 30 nm. MX 11 is vacuum deposited on the green emitting EML, to form an electron transport layer (ETL) having a thickness of 35 nm. LiQ is vacuum deposited on the ETL to form an electron injection layer (EIL) having a thickness of 2 nm. Aluminium is vacuum deposited on the EIL to form a cathode having a thickness of 100 nm.

The OLED stack is protected from ambient conditions by encapsulation of the device with a glass slide. Thereby, a cavity is formed, which includes a getter material for further protection.

The performance is assessed as described in the general procedure for single OLEDs.

In Table 14 below the performance of tandem OLEDs with a first and second ETL, wherein the first ETL comprises a Li organic complex and the second ETL comprises a metal dopant compared to comparative example 9 with a single ETL comprising a metal dopant.

The examples 26 to 28 in Table 14 comprise the charged generation layer without an interlayer (IL). In more detail, the tandem OLEDs according to Table 14 comprises a layer structure in the following order:

Substrate **110**/anode electrode **120**/first hole injection layer **130**/first hole transport layer **140**/first emission layer (fluorescent blue emitting layer) **150**/first electron transport layer **161**/second electron transport layer **162**/second hole injection layer **131**/second hole transport layer **141**/triplet control layer **170**/second emission layer (phosphorescent green emitting layer) **151**/third electron transport layer **163**/electron injection layer **180**/ and a cathode electrode **190**.

TABLE 14

External quantum efficiency (EQE) and lifetime of bottom emission tandem OLEDs with two ETLs and two emission layers										
	ETL1	wt.-% Li organic complex * ¹	d (ETL1)/ nm	ETL2	wt.-% Metal dopant * ²	vol.-% Metal dopant * ³	d (ETL2)/ nm	V at 10 mA/cm ² /V	EQE/ %	LT/ h
Comp. exa. 9	—	—	—	MX4:Yb	5	1	30	6.9	22.7	45
Exa. 26	MX4:Li-2	50	14	MX4:Yb	5	1	16	8.2	25.5	82
Exa. 27	MX4:Li-2	50	14	MX4:Li	0.5	1	16	7.8	25.9	60
Exa. 28	MX4:Li-2	49	13	MX10:Li	0.5	1	17	7.9	24.6	64

*¹ = the wt.-% of the matrix compound and the wt.-% of the lithium organic complex are in total 100 wt.-% based on weight of the ETL1

*² = the wt.-% of the matrix compound and the wt.-% of the elemental metal are in total 100 wt.-% based on weight of the ETL2

*³ = the vol.-% of the matrix compound and the vol.-% of the elemental metal are in total 100 vol.-% based on weight of the ETL2

matrix compound from a first deposition source, if the same matrix compound is used as in the first electron transport layer, or a third deposition source, if the matrix compound is different from the matrix compound used in the first electron transport layer. 92 wt.-% of Biphenyl-4-yl(9,9-diphenyl-9H-fluoren-2-yl)-[4-(9-phenyl-9H-carbazol-3-yl)phenyl]-amine and 8 wt.-% of 2,2',2''-(cyclopropane-1,2,3-triylidene)tris(2-(p-cyanotetrafluorophenyl)acetonitrile) was vacuum deposited on the second electron transport layer (ETL 2), to form a HIL having a thickness of 10 nm. Then Biphenyl-4-yl(9,9-diphenyl-9H-fluoren-2-yl)-[4-(9-phenyl-9H-carbazol-3-yl)phenyl]-amine was vacuum deposited on the HIL, to form a HTL having a thickness of 30 nm. Then N3,N3'-di([1,1'-biphenyl]-4-yl)-N3,N3'-dimesityl-[1,1'-biphenyl]-3,3'-diamine (CAS 1639784-29-4) was vacuum deposited on the HTL to form a triplet control layer having

As can be seen in Table 14 above, the performance is compared of Example 26 with a first ETL comprising a phosphine oxide matrix compound and a Li organic complex and comparative example 9 without first ETL. Efficiency and LT are significantly improved, thereby demonstrating the benefit of devices comprising a first ETL.

In Example 26, Li is used as metal dopant compared to Yb dopant in Example 27. The same volume percentage of metal dopant is used for both examples. Comparable LT and efficiency are achieved for these different metal dopants.

In Example 28, a phenanthroline matrix compound, MX 10, is used in the second ETL. Efficiency and LT are comparable to Example 27, where a phosphine oxide matrix compound, MX 4, was used.

In conclusion, high efficiency and LT are obtained for tandem OLED devices which comprise a first and second ETL.

55

The double ETL of a first electron transport layer and of a second electron transport layer as well as the triple ETL of a first electron transport layer, a second electron transport layer and a third electron transport layer could also be employed for other emission colors, for example green, red, and white-light emitting devices.

Another aspect is directed to a device comprising at least one organic light-emitting diode (OLED). A device comprising organic light-emitting diodes is for example a display or a lighting panel.

From the foregoing detailed description and examples, it will be evident that modifications and variations can be made to the compositions and methods of the invention without departing from the spirit and scope of the invention. Therefore, it is intended that all modifications made to the invention without departing from the spirit and scope of the invention come within the scope of the appended claims.

The invention claimed is:

1. An organic light-emitting diode (OLED) comprising an emission layer and an electron transport layer stack of at least two electron transport layers, wherein a first electron transport layer and a second electron transport layer comprise at least one matrix compound, wherein the first electron transport layer comprises a first matrix compound, and the second electron transport layer comprises a second matrix compound that is a phosphine oxide based compound; and in addition,

the at least first electron transport layer comprises a lithium halide or a lithium organic complex; and the at least second electron transport layer comprises an elemental metal selected from the group of lithium, magnesium and/or ytterbium;

wherein the electron transport layer or layers comprising a lithium halide or a lithium organic complex is free of an elemental metal, and the electron transport layer or layers that comprises an elemental metal is free of a metal salt and/or a metal organic complex;

wherein for an electron transport layer stack of two electron transport layers the first electron transport layer is arranged closest to at least one emission layer, and the second electron transport layer is arranged closest to a cathode electrode.

2. An organic light-emitting diode (OLED) according to claim 1, wherein the matrix compounds of the electron transport layer stack are different for each electron transport layer, except for the phosphine oxide matrix compound.

3. The OLED comprising the electron transport layer stack according to claim 1, wherein

the amount of the lithium halide or lithium organic complex in an electron transport layer is in the range of about >10 mol-% to about <95 mol-% of the corresponding electron transport layer; and/or

the amount of the lithium halide or lithium organic complex in an electron transport layer stack of at least three electron transport layers, and/or at least two of the electron transport layers is in the range of about >10 mol-% to about <95 mol-% of the corresponding electron transport layer.

4. The OLED comprising the electron transport layer stack according to claim 1, wherein

at least one electron transport layer, comprises about >1 wt.-% to about <60 wt.-% of an elemental metal selected from the group of lithium, magnesium and/or ytterbium; or

at least two electron transport layer of at least three electron transport layers comprises about >1 wt.-% to about <60 wt.-% of an elemental metal selected from

56

the group of lithium, magnesium and/or ytterbium; wherein the weight percent of the elemental metal selected from the group of lithium, magnesium and/or ytterbium is based on the total weight of the corresponding electron transport layer.

5. The OLED comprising the electron transport layer stack according to claim 1, wherein the lithium halide is selected from a group comprising LiF, LiCl, LiBr or LiI, and the organic ligand of the lithium organic complex is a quinolate, a borate, a phenolate, a pyridinolite or a Schiff base ligand.

6. The OLED comprising the electron transport layer stack according to claim 1, wherein the electron transport layer stack comprises at least two electron transport layers or at least three electron transport layers, and wherein each electron transport layer comprises at least one matrix compound, whereby the matrix compound of the electron transport layers are selected same or different.

7. The OLED comprising the electron transport layer stack according to claim 1, wherein the at least two electron transport layers or at least three electron transport layers comprise at least one matrix compound, whereby the matrix compound of the electron transport layers are selected same or different, and wherein the first matrix compound is selected from:

an anthracene based compound or a heteroaryl substituted anthracene based compound;

a phosphine oxide based compound; or

a substituted phenanthroline compound.

8. The OLED comprising the electron transport layer stack according to claim 1, wherein the thicknesses of each electron transport layer are same or each independently in the range of about >0.5 nm to about <95 nm.

9. The OLED comprising the electron transport layer stack according to claim 1, wherein the thicknesses of the electron transport layer stack is in the range of about >25 nm to about <100 nm.

10. The OLED comprising the electron transport layer stack according to claim 1, wherein the electron transport layer stack has two to four electron transport layers.

11. The OLED comprising the electron transport layer stack according to claim 1, wherein the at least second electron transport layer is formed directly on the at least first electron transport layer and/or an at least third electron transport layer is formed directly on the at least second electron transport layer so that the second electron transport layer is sandwiched between the first electron transport layer and the third electron transport layer.

12. The OLED comprising the electron transport layer stack according to claim 1, wherein

at least one electron transport layer or in case of at least three electron transport layers at least two electron transport layer comprise: a) about >10 wt.-% to about <70 wt.-% of a lithium halide, selected from the group comprising a LiF, LiCl, LiBr or LiI, or of a lithium organic complex, selected from the group comprising a lithium quinolate, a borate, a phenolate, a pyridinolite or a Schiff base ligand;

b) about <90 wt.-% to about >30 wt.-% of a matrix compound of:

an anthracene based compound or a heteroaryl substituted anthracene based compound;

a phosphine oxide based compound;

a substituted phenanthroline compound; and

at least one electron transport layer or in case of at least three electron transport layers at least two electron layers comprise:

57

c) about >1 wt.-% to about <60 wt.-% of an elemental metal selected from the group of lithium, magnesium and/or ytterbium;

d) about <99 wt.-% to about >40 wt.-% of a matrix compound of:

a phosphine oxide based compound.

13. The OLED comprising the electron transport layer stack according to claim 1, wherein

the at least one lithium organic complex containing electron transport layer comprises of about >50 wt.-% to about <60 wt.-% of a lithium 8-hydroxyquinolate and about <50 wt.-% to about >40 wt.-% of a (3-(dibenzo [c,h]acridin-7-yl)phenyl)diphenylphosphine oxide; and the at least one elemental metal containing electron transport layer comprises of about >2 wt.-% to about <45 wt.-% of an elemental metal selected from the group of lithium, magnesium and/or ytterbium.

14. The OLED according to claim 1 comprising: a substrate; a first anode electrode is formed on the substrate; the cathode electrode is formed on the at least first anode electrode; and the electron transport layer stack arranged between the at least first anode electrode and the cathode electrode, comprising or consisting of the at least two electron transport layers or of at least three electron transport layers.

15. The OLED according to claim 1, further comprising at least one layer selected from the group consisting of a hole injection layer, a hole transport layer and a hole blocking layer, arranged between an at least first anode electrode and the electron transport layer stack.

16. The OLED according to claim 1, further comprising an electron injection layer arranged between the electron transport layer stack and the cathode electrode.

17. The OLED according to claim 1, comprising the following layers arranged in the order of a substrate, an anode electrode, a first hole injection layer, a first hole transport layer, optional a first triplet control layer, a first emission layer, the first electron transport layer, the second electron transport layer, an optional interlayer, a second hole injection layer, a second hole transport layer, optional a second triplet control layer, a second emission layer, an optional electron transport layer, optional a third electron transport layer, an optional injection layer, and the cathode electrode.

18. A method of manufacturing an organic light-emitting diode according to claim 1, the method comprising: deposition via at least three deposition sources; or deposition via vacuum thermal evaporation; or deposition via solution processing.

19. A method of manufacturing an organic light-emitting diode according to claim 18, the method comprising:

a first or a first and a fourth deposition source to release the matrix compound, and

a second deposition source to release lithium halide or lithium organic complex, and

a third deposition source to release the elemental metal, at least one or two deposition sources to release the matrix compound, and

at least one or two deposition sources to release lithium halide or lithium organic complex, and

the method comprising the steps of forming the electron transport layer stack; whereby

a first electron transport layer is formed by releasing the matrix compound from at least one deposition source and a lithium halide or a lithium organic complex or an elemental metal is released from at different deposition source;

58

onto the first electron transport layer a second electron transport layer is formed by releasing the matrix compound from at least one deposition source and a lithium halide or a lithium organic complex or an elemental metal is released from at different deposition source;

onto the second electron transport layer a third electron transport layer is formed by releasing the matrix compound from at least one deposition source and a lithium halide or a lithium organic complex or an elemental metal is released from at different deposition source; whereby

at least one electron transport layer comprises a lithium halide or a lithium organic complex and is free of an elemental metal; and at least one electron transport layer comprises an elemental metal and is free of a lithium halide or a lithium organic complex.

20. The method of claim 18, comprising the steps, wherein

on a substrate a first anode electrode is formed,

on the first anode electrode an emission layer is formed, on the emission layer an electron transport layer stack is formed,

comprising at least two electron transport layers, or at least three electron transport layers,

on the electron transport layer stack a second cathode electrode is formed,

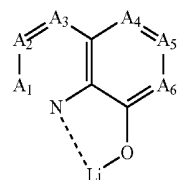
optional a hole injection layer, a hole transport layer, an emission layer, and a hole blocking layer, are formed in that order between the at least first anode electrode and the electron transport layer stack,

optional an electron injection layer is arranged between the electron transport layer stack and the at least second cathode electrode.

21. A device comprising at least one organic light-emitting diode of claim 1.

22. The OLED comprising at least one emission layer, and an electron transport layer stack of at least two electron transport layers according to claim 1, wherein the phosphine oxide based compound is selected from (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1',2'-f]phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide, or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide.

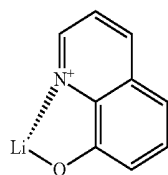
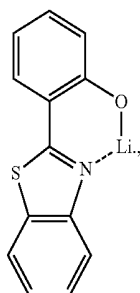
23. The OLED comprising the electron transport layer stack according to claim 5, wherein the lithium quinolate complex has the formula I, II, or III:



(I)

59

-continued



wherein

A1 to A6 are same or independently selected from CH, CR, N, O;

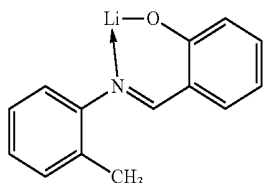
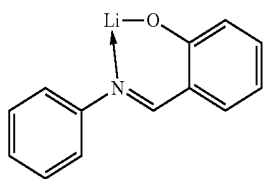
R is same or independently selected from hydrogen, halogen, alkyl or aryl or heteroaryl with 1 to 20 carbon atoms.

24. The OLED comprising the electron transport layer stack according to claim 5, wherein the borate based organic ligand is a tetra(1H-pyrazol-1-yl)borate.

25. The OLED comprising the electron transport layer stack according to claim 5, wherein the phenolate is a 2-(pyridin-2-yl)phenolate, a 2-(diphenylphosphoryl)phenolate, an imidazol phenolate, 2-(pyridin-2-yl)phenolate, or 2-(1-phenyl-1H-benzo[d]imidazol-2-yl)phenolate.

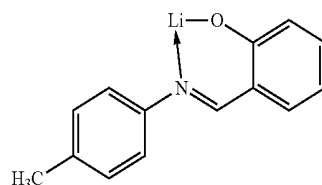
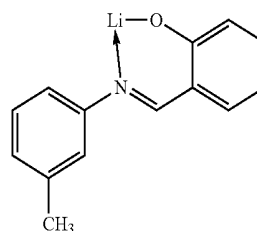
26. The OLED comprising the electron transport layer stack according to claim 5, wherein the pyridinolate is a 2-(diphenylphosphoryl)pyridin-3-olate.

27. The OLED comprising the electron transport layer stack according to claim 5, wherein the lithium Schiff base has the structure 100, 101, 102 or 103:



60

-continued



(II)

102

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(III)

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28. The OLED comprising the electron transport layer stack according to claim 7, wherein the anthracene based compound or the heteroaryl substituted anthracene based compound is selected from 2-(4-(9, 10-di(naphthalen-2-yl)anthracene-2-yl)phenyl)-1-phenyl-1H-benzo[d]imidazole, 1-(4-(10-([1, 1'-biphenyl]-4-yl)anthracen-9-yl)phenyl)-2-ethyl-1H-benzo[d]imidazole, or N4,N4"-di(naphthalen-1-yl)-N4,N4"-diphenyl-[1, 1':4',1"-terphenyl]-4,4"-diamine.

29. The OLED comprising the electron transport layer stack according to claim 7, wherein the phosphine oxide based compound is selected from (3-(dibenzo[c,h]acridin-7-yl)phenyl)diphenylphosphine oxide, 3-phenyl-3H-benzo[b]dinaphtho[2,1-d:1'2']phosphine-3-oxide, bis(4-(anthracen-9-yl)phenyl)(phenyl)phosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, (3-(9,10-di(naphthalen-2-yl)anthracen-2-yl)phenyl)diphenylphosphine oxide, phenyldi(pyren-1-yl)phosphine oxide, diphenyl(5-(pyren-1-yl)pyridin-2-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1, 1'-biphenyl]-3-yl)phosphine oxide, diphenyl(4'-(pyren-1-yl)-[1,1'-biphenyl]-3-yl)phosphine oxide, (3'-(dibenzo[c,h]acridin-7-yl)-[1,1'-biphenyl]-4-yl)diphenylphosphine oxide, or phenyl bis(3-(pyren-1-yl)phenyl)phosphine oxide.

30. The OLED comprising the electron transport layer stack according to claim 7, wherein the substituted phenanthroline compound is selected from 2,4,7,9-tetraphenyl-1, 10-phenanthroline, 4,7-diphenyl-2,9-di-p-tolyl-1, 10-phenanthroline, or 2,9-di(biphenyl-4-yl)-4,7-diphenyl-1, 10-phenanthroline.

* * * * *

专利名称(译)	有机发光二极管,包括电子传输层堆叠,该电子传输层堆叠包含不同的锂化合物和元素金属		
公开(公告)号	US10700300	公开(公告)日	2020-06-30
申请号	US15/512314	申请日	2015-09-17
[标]申请(专利权)人(译)	诺瓦莱德公开股份有限公司		
申请(专利权)人(译)	Novaled公司GMBH		
当前申请(专利权)人(译)	Novaled公司GMBH		
[标]发明人	WALLIKEWITZ BODO ROTHER CARSTEN		
发明人	WALLIKEWITZ, BODO ROTHER, CARSTEN		
IPC分类号	H01L51/50		
CPC分类号	H01L51/5076 H01L51/508 H01L51/5088		
优先权	2014185560 2014-09-19 EP		
其他公开文献	US20170279064A1		
外部链接	Espacenet		

摘要(译)

本发明涉及一种有机发光二极管(OLED,100),该有机发光二极管包括至少一个发射层(150)和至少一个电子传输层堆叠(160)。至少两个电子传输层,其中第一电子传输层(161, 162)和第二电子传输层(162, 161)包括至少一种基质化合物,此外,-至少第一电子传输层 包含卤化锂或锂有机配合物;至少第二电子传输层包括选自锂,镁和/或的元素金属;或者-至少第一电子传输层包含选自锂,镁和/或的元素金属;至少第二电子传输层包含卤化锂或锂有机络合物。其中包含卤化锂或锂有机配合物的一个或多个电子传输层不包含元素金属,并且包含元素金属的一个或多个电子传输层不包含金属盐和/或金属有机配合物。

